Power Matters.

POWER PORTFOLIO 2012-2013



Power Semiconductors

Power Modules

RF Power MOSFETs

Microsemi

About Microsemi

Microsemi Corporation (Nasdaq: MSCC) offers a comprehensive portfolio of semiconductor and system solutions for communications, defense & security, aerospace and industrial markets. Products include high-performance, radiation-hardened and highly reliable analog mixed-signal integrated circuits, FPGAs, SoCs and ASICs; power management products; timing and voice processing devices; RF solutions; discrete components; security technologies and scalable anti-tamper products; Power-over-Ethernet ICs and midspans; as well as custom design capabilities and services.

Microsemi is headquartered in Aliso Viejo, Calif., and has approximately 3,000 employees globally. Learn more at www.microsemi.com.

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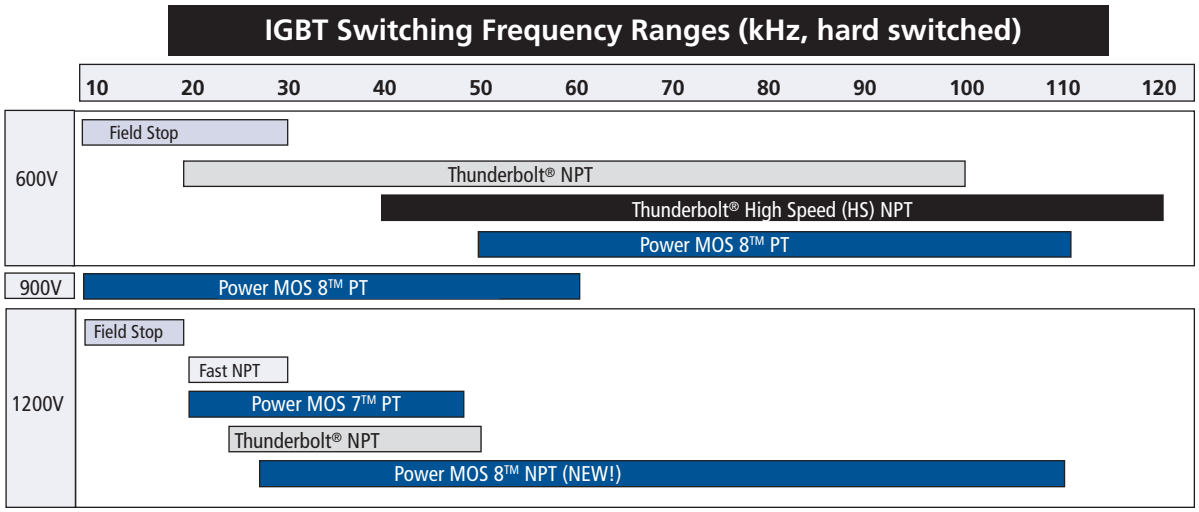
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"COOLMOS" comprise a new family of transistors developed by Infineon Technologies AG.
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Insulated Gate Bipolar Transistors (IGBTs)

IGBTs from Microsemi

IGBT products from Microsemi provide high quality solutions for a wide range of high voltage, high power applications. The switching frequency range spans from DC for minimal conduction loss to over 100kHz for very high power density SMPS applications. The frequency range for each product type is shown in the graph below. Each IGBT product represents the latest in IGBT technology, providing the best possible performance/cost combination for the targeted application. There are six product series that utilize three different IGBT technologies: Non-Punch-Through (NPT), Punch-Through (PT) and Field Stop.



Note: Frequency ranges shown are typical for a 50A IGBT. Refer to product data sheet max frequency vs current graph for more information.

Standard Series	Voltage Ratings (V)	Technology	Easy to Parallel	Short Circuit SOA	Comment
Thunderbolt®	600, 1200	NPT	X	X	General purpose, high speed
Thundebolt® High Speed	600	NPT	X	X	Highest speed
FAST	1200	NPT	X	X	General purpose, medium speed
MOS 7™	1200	PT			Ultra-low gate charge
MOS 8™	600, 900, 1200	PT, NPT			Highest efficiency
Field Stop Trench Gate	600, 1200	Field Stop	X	X	Lowest conduction loss

Product Options

All standard IGBT products are available as a single IGBT or as a Combi product packaged with an anti-parallel DQ series diode. Package options include TO-220, TO-247, T-MAX®, TO-264, and SOT-227. Customized products are available; contact factory for details.

Insulated Gate Bipolar Transistors (IGBTs)

POWER MOS 8™

New!
1200V

- NPT Technology
- High Speed Switching
- Low Switching Losses
- Easy to Parallel

POWER MOS 8™

- PT Technology
- Fast Switching
- Highest Efficiency
- Combi with High Speed DQ Diode

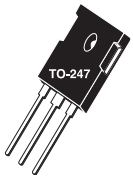
FIELD STOP

- Trench Technology
- Short Circuit Rated
- Lowest Conduction Loss
- Easy Paralleling
- Combi with High Speed DQ Diode

BV_{CES} Volts	$V_{CE(ON)}$ Typ 25°C	I_{C2} 100°C	Maximum I_C at Frequency		Part Number	Package Style
SINGLE			**50 kHz**	**80 kHz**		
1200	2.5	25	25	21	APT25GR120B	TO-247
	2.5	25	25	21	APT25GR120S	D^3
	2.5	40	38	28	APT40GR120B	TO-247
	2.5	40	38	28	APT40GR120S	D^3
	2.5	50	48	36	APT50GR120B2	T-MAX®
	2.5	50	48	36	APT50GR120L	TO-264
			25 kHz	**50 kHz**		
	2.5	70	66	42	APT70GR120B2	T-MAX®
	2.5	70	66	42	APT70GR120L	TO-264
	2.5	70	42	30	APT70GR120J	ISOTOP®
	2.5	85	72	46	APT85GR120B2	T-MAX®
	2.5	85	72	46	APT85GR120L	TO-264
	2.5	85*	46	31	APT85GR120J	ISOTOP®
Combi (IGBT & Diode)			**50 kHz**	**80 kHz**		
1200	2.5	25	25	21	APT25GR120BD15	TO-247 (DQ)
	2.5	25	25	21	APT25GR120SD15	D3 (DQ)
	2.5	25	25	21	APT25GR120BSCD10	TO-247 (SiC SBD)
	2.5	25	25	21	APT25GR120SSCD10	D3 (SiC SBD)
	2.5	40	38	28	APT40GR120B2D30	T-MAX® (DQ)
	2.5	40	38	28	APT40GR120B2SCD10	T-MAX® (SiC SBD)
			25 kHz	**50 kHz**		
	2.5	50*	42	32	APT50GR120JD30	ISOTOP® (DQ)
	2.5	70*	42	30	APT70GR120JD60	ISOTOP® (DQ)
	2.5	85*	46	31	APT85GR120JD60	ISOTOP® (DQ)
SINGLE			**50 kHz**	**80 kHz**		
600	2.0	36	21	17	APT36GA60B	TO-247
	2.0	44	26	20	APT44GA60B	TO-247
	2.0	54	30	23	APT54GA60B	TO-247
	2.0	68	35	27	APT68GA60B	TO-247
	2.0	80	40	31	APT80GA60B	TO-247
	2.0	102	51	39	APT102GA60B2	T-MAX® or TO-264
			25 kHz	**50 kHz**		
900	2.5	35	17	10	APT35GA90B	TO-247
	2.5	43	21	13	APT43GA90B	TO-247
	2.5	64	29	19	APT64GA90B	TO-247
	2.5	80	34	23	APT80GA90B	TO-247 or D^3
Combi (IGBT & "DQ" FRED)			**50 kHz**	**80 kHz**		
600	2.0	36	21	17	APT36GA60BD15	TO-247
	2.0	44	26	20	APT44GA60BD30	TO-247
	2.0	54	30	23	APT54GA60BD30	TO-247
	2.0	60	48	36	APT60GA60JD60	ISOTOP®
	2.0	68	35	27	APT68GA60B2D40	T-MAX® or TO-264
	2.0	80	40	31	APT80GA60LD40	TO-264
			25 kHz	**50 kHz**		
900	2.5	27	14	8	APT27GA90BD15	TO-247
	2.5	35	17	10	APT35GA90BD15	TO-247
	2.5	43	21	13	APT43GA90BD30	TO-247
	2.5	46	33	21	APT46GA90JD40	ISOTOP®
	2.5	64	29	19	APT64GA90B2D30	T-MAX® or TO-264
	2.5	80	34	23	APT80GA90LD40	TO-264
SINGLE			**15 kHz**	**30 kHz**		
600	1.5	24	15	10	APT20GN60BG	TO-247
	1.5	37	20	14	APT30GN60BG	TO-247
	1.5	64	30	21	APT50GN60BG	TO-247
	1.5	93	42	30	APT75GN60BG	TO-247
	1.5	123	75	47	APT150GN60J	ISOTOP®
	1.5	135	54	39	APT100GN60B2G	T-MAX®
	1.5	190	79	57	APT150GN60B2G	T-MAX®
	1.5	230	103	75	APT200GN60B2G	T-MAX®
	1.5	158	100	66	APT200GN60J	ISOTOP®
			10 kHz	**20 kHz**		
1200	1.7	33	19	13	APT25GN120BG	TO-247 or D^3
	1.7	46	24	17	APT35GN120BG	TO-247
	1.7	66	32	22	APT50GN120B2G	T-MAX®
	1.7	70	44	27	APT100GN120J	ISOTOP®
	1.7	99	45	30	APT75GN120B2G	T-MAX® or TO-264
	1.7	120	58	38	APT100GN120B2G	T-MAX®
	1.7	99	60	36	APT150GN120J	ISOTOP®

Current @ Frequency Test Conditions: Tj = 125°C, Tc = 100°C except Isotop® where Tc = 80°C, Vcc = 67% rated voltage Hard Switch

* Ic2 for ISOTOP® packages measured at 70°C for 1200V NPT IGBTs



TO-247[B]

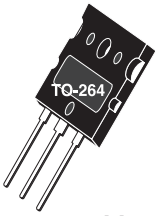


D^3 PAK[S]

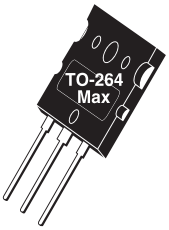
Part Numbers for D^3 packages - replace B" with "S" in part number



T-MAX®[B2]

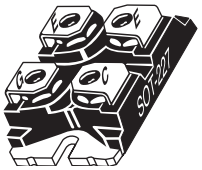


TO-264[L]



264-MAX™[L2]

Part Numbers for TO-264 packages - replace "B2" with "L" in part number



ISOTOP®[J]
SOT-227



Insulated Gate Bipolar Transistors (IGBTs)

Power MOS 7® and IGBT

- PT Technology
- Ultra-low Gate Charge
- Combi with High Speed DQ Diode

THUNDERBOLT®

- NPT Technology
- Short Circuit Rated
- Moderate to High Frequency
- Easy Paralleling

THUNDERBOLT® HIGH SPEED

- High Speed Switching - Reduced Eoff
- Fastest Switching
- NPT Technology

BV_{CES} Volts	$V_{CE(ON)}$ Typ 25°C	I_{C2} 100°C	Maximum I_C at Frequency		Part Number	Package Style
Combi (IGBT & "DQ" FRED)			15 kHz	30 kHz		
600	1.5	24	15	10	APT20GN60BDQ1G	TO-247
	1.5	37	20	14	APT30GN60BDQ2G	TO-247
	1.5	64	30	21	APT50GN60BDQ2G	TO-247
	1.5	93	42	30	APT75GN60LDQ3G	TO-264
	1.5	123	75	47	APT150GN60JDQ4	ISOTOP®
	1.5	135	54	39	APT100GN60LDQ4G	TO-264
	1.5	190	79	57	APT150GN60LDQ4G	TO-264
	1.5	158	100	66	APT200GN60JDQ4	ISOTOP®
			10 kHz	20 kHz		
1200	1.7	22	14	10	APT15GN120BDQ1G	TO-247 or D³
	1.7	33	19	13	APT25GN120B2DQ2G	T-MAX®
	1.7	46	24	17	APT35GN120L2DQ2G	264-MAX™
	1.7	57	36	22	APT75GN120JDQ3	ISOTOP®
	1.7	66	32	22	APT50GN120L2DQ2G	264-MAX™
	1.7	70	44	27	APT100GN120JDQ4	ISOTOP®
	1.7	99	60	36	APT150GN120JDQ4	ISOTOP®
SINGLE			20 kHz	40 kHz		
1200	3.3	33	19	12	APT25GP120BG	T0-247
	3.3	46	24	15	APT35GP120BG	T0-247
	3.3	54	29	18	APT45GP120BG	T0-247
	3.3	34	28	18	APT45GP120J	ISOTOP
	3.3	91	42	24	APT75GP120B2G	T-MAX™
	3.3	57	40	23	APT75GP120J	ISOTOP
Combi (IGBT & "DQ" FRED)			20 kHz	40 kHz		
1200	3.3	20	11	7	APT13GP120BDQ1G	T0-247
	3.3	33	19	12	APT25GP120BDQ1G	T0-247
	3.3	46	24	15	APT35GP120B2DQ2G	T-MAX™
	3.3	54	29	18	APT45GP120B2DQ2G	T-MAX™
	3.3	34	28	18	APT45GP120JDQ2	ISOTOP
	3.3	57	40	23	APT75GP120JDQ3	ISOTOP
SINGLE			30 kHz	60 kHz		
600	2.0	20	14	10	APT20GT60BRG	TO-247
	2.0	30	19	13	APT30GT60BRG	TO-247
	2.0	40	25	16	APT40GT60BRG	TO-247
	2.0	50	30	20	APT50GT60BRG	TO-247
	2.0	60	35	22	APT60GT60BRG	TO-247 or D³
	2.0	100	56	35	APT100GT60B2RG	T-MAX® or TO-264
	2.0	200	72	--	APT200GT60JR	ISOTOP®
			20 kHz	40 kHz		
1200	3.2	18	11	8	APT15GT120BRG	TO-247
	3.2	25	16	11	APT25GT120BRG	TO-247
	3.2	50	27	17	APT50GT120B2RG	T-MAX® or TO-264
	3.2	60	40	21	APT100GT120JR	ISOTOP®
	3.2	90	52	25	APT150GT120JR	ISOTOP®
Combi (IGBT & "DQ" FRED)			30 kHz	60 kHz		
600	2.0	15	11	8	APT15GT60BRDQ1G	TO-247
	2.0	20	14	10	APT20GT60BRDQ1G	TO-247
	2.0	30	19	13	APT30GT60BRDQ2G	TO-247
	2.0	50	30	20	APT50GT60BRDQ2G	TO-247 or D³
	2.0	100	37	22	APT100GT60JRDQ4	ISOTOP®
			20 kHz	40 kHz		
1200	3.2	18	11	8	APT15GT120BRDQ1G	TO-247
	3.2	25	16	11	APT25GT120BRDQ2G	TO-247
	3.2	50	27	17	APT50GT120B2RDQ2G	T-MAX® or TO-264
	3.2	42	34	19	APT75GT120JRDQ3	ISOTOP®
	3.2	60	40	21	APT100GT120JRDQ4	ISOTOP®
SINGLE			50 kHz	80 kHz		
600	2.8	50	23	16	APT50GS60BRG	TO-247
Combi (IGBT & "DQ" FRED)			50 kHz	80 kHz		
600	2.8	30	14	9	APT30GS60BRDQ2G	TO-247
	2.8	50	23	16	APT50GS60BRDQ2G	TO-247
SINGLE			15 kHz	30 kHz		
1200	2.5	14	8	5	APT11GF120KRG	TO-220
	2.5	20	11	7	APT20GF120KRG	TO-220
	2.5	35	16	10	APT33GF120BRG	TO-247
	2.5	75	27	17	APT50GF120B2RG	T-MAX®
	2.5	75	27	17	APT50GF120LRG	TO-264

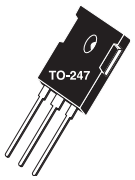
Current @ Frequency Test Conditions: Tj = 125°C, Tc = 100°C except Isotop® where Tc = 80°C, Vcc = 67% rated voltage Hard Switch



TO-220[K]



D³ PAK[S]

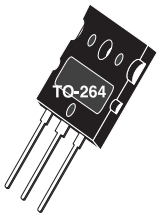


TO-247[B]

Part Numbers for D³ packages - replace "B" with "S" in part number

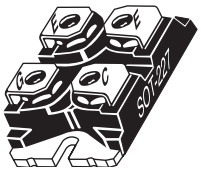


T-MAX®[B2]



TO-264[L]

Part Numbers for L packages - replace "B2" with "L" in part number



ISOTOP®[J]
SOT-227



Insulated Gate Bipolar Transistors (IGBTs)

FAST

- NPT Technology
- Short Circuit Rated
- Low to Moderate Freq.
- Low Conduction Loss
- Easy Paralleling

BV_{CES} Volts	$V_{CE(ON)}$ Typ 25°C	I_{C2} 100°C	Maximum I_C at Frequency		Part Number	Package Style
Combi (IGBT & "DQ" FRED)			15 kHz	30 kHz		
1200	2.5	35	16	10	APT33GF120B2RDQ2G	T-MAX®
	2.5	64	33	17	APT50GF120JRDQ3	ISOTOP®
	2.5	80	42	20	APT60GF120JRDQ3	ISOTOP®
Combi (IGBT & "DL" FRED)			50 kHz	80 kHz		
600	2.8	50	23	16	APT50GS60BRDLG	TO-247
	2.8	30	14	9	APT30GS60BRDLG	TO-247
	2.2	50	41	31	APT50GP60LDL	TO-264
	2.2	45	28	22	APT30GP60B2DL	T-MAX® or TO-264
	2.2	25	17	14	APT15GP60BDL	TO-247
			20 kHz	40 kHz		
1200	3.2	50	28	17	APT50GT120B2RDL	T-MAX®
	3.2	100	40	21	APT100GT120JRDL	ISOTOP®

Power MOS 8™ MOSFETs / FREDFETs
(fast body diode)

Power MOS 8™ is Microsemi's latest family of high speed, high voltage (500-1200V) N-channel switch-mode power transistors with lower EMI characteristics and lower cost compared to previous generation devices. These new MOSFETs / FREDFETs have been optimized for both hard and soft switching in high frequency, high voltage applications rated above 500W. There are 2 product types in the Power MOS 8™ MOSFET family:



1) **MOSFET**
2) **FREDFETs** have a fast recovery body diode characteristic, providing high commutation dv/dt ruggedness and high reliability in ZVS circuits.

Features

- Fast switching
- Low EMI
- Quiet switching
- Avalanche energy rated
- Low gate charge
- Lower cost

Applications

- Power factor correction
- Server and telecom power systems
- Solar inverters
- Semiconductor capital equipment
- Induction heating
- Arc welding
- Plasma cutting
- Battery chargers
- Medical

Quiet Switching

The new Power MOS 8™ series is a result of extensive research into quiet switching. Input and reverse transfer capacitance values as well as their ratio were set at specific values to achieve quiet switching with minimal switching loss. The Power MOS 8™ series of devices are inherently quiet switching, stable when connected in parallel, very efficient, and lower cost than previous generations.

Body Diode Options

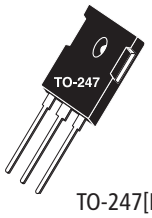
As with previous generation products, Power MOS 8™ MOSFETs and FREDFETs are available in all voltage ratings. A FREDFET is a MOSFET with a faster recovery intrinsic body diode. This results in improved reliability in ZVS circuits due to shorter minority carrier lifetime and increased commutation dv/dt ruggedness. If a fast recovery body diode is not needed, MOSFET versions are available.

Power MOS 8™ MOSFETs / FREDFETs

$BV_{(DSS)}$ Volts	$R_{DS(ON)}$ Max	I_D	MOSFET Part #	I_D	FREDFET Part #	Package Style
1200	3.80	5	APT4M120K			TO-220
	4.20			4	APT4F120K	TO-220
	2.40			7	APT7F120B	TO-247 or D^3
	2.10	8	APT7M120B			TO-247
	1.20			14	APT13F120B	TO-247 or D^3
	1.10	14	APT14M120B			TO-247
	0.70			23	APT22F120B2	T-MAX® or TO-264
	0.63	24	APT24M120B2			T-MAX® or TO-264
	0.58			27	APT26F120B2	T-MAX® or TO-264
	0.58			18	APT17F120J	ISOTOP®
	0.53	29	APT28M120B2			T-MAX® or TO-264
	0.53	19	APT19M120J			ISOTOP®
	0.32			33	APT32F120J	ISOTOP®
	0.29	35	APT34M120J			ISOTOP®
1000	2.80			5	APT5F100K	TO-220
	2.50	6	APT6M100K			TO-220
	2.00			7	APT7F100B	TO-247
	1.80	8	APT8M100B			TO-247
	1.60			9	APT9F100B	TO-247 or D^3
	1.40	9	APT9M100B			TO-247
	0.98			14	APT14F100B	TO-247 or D^3
	0.88	14	APT14M100B			TO-247 or D^3
	0.78			17	APT17F100B	TO-247 or D^3
	0.70	18	APT18M100B			TO-247
	0.44			30	APT29F100B2	T-MAX® or TO-264
	0.44			20	APT19F100J	ISOTOP®
	0.38	32	APT31M100B2	35	APT34F100B2	T-MAX® or TO-264
	0.38	21	APT21M100J	23	APT22F100J	ISOTOP®
	0.33	37	APT37M100B2			T-MAX® or TO-264
	0.33	25	APT25M100J			ISOTOP®
	0.20			42	APT41F100J	ISOTOP®
	0.18	45	APT45M100J			ISOTOP®
800	1.50			7	APT7F80K	TO-220
	1.35	8	APT8M80K			TO-220
	0.90			12	APT11F80B	TO-247 or D^3
	0.80	13	APT12M80B			TO-247
	0.58			18	APT17F80B	TO-247 or D^3
	0.53	19	APT18M80B			TO-247 or D^3
	0.43			23	APT22F80B	TO-247 or D^3
	0.39	25	APT24M80B			TO-247 or D^3
	0.24			41	APT38F80B2	T-MAX® or TO-264
	0.21	43	APT41M80B2	47	APT44F80B2	T-MAX® or TO-264
	0.21			31	APT29F80J	ISOTOP®
	0.19	49	APT48M80B2			T-MAX® or TO-264
	0.19	33	APT32M80J			ISOTOP®
	0.11			57	APT53F80J	ISOTOP®
	0.10	60	APT58M80J			ISOTOP®



TO-220[K]



TO-247[B]

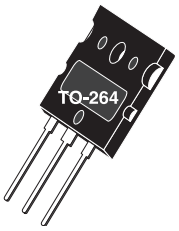


D^3 PAK[S]

Part Numbers for D^3 packages - replace "B" with "S" in part number

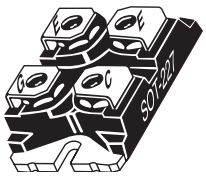


T-MAX®[B2]



TO-264[L]

Part Numbers for TO-264 packages - replace "B2" with "L" in part number



ISOTOP®[J]
SOT-227
(ISOLATED BASE)

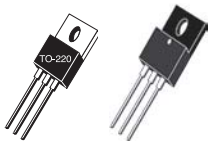
Power MOS 8™ MOSFETs / FREDFETs

$BV_{(DSS)}$ Volts	$R_{DS(ON)}$ Max	I_D	MOSFET Part #	I_D	FREDFET Part #	Package
600	0.62			12	APT12F60K	TO-220
	0.43			16	APT15F60B	TO-247 or D^3
	0.37			19	APT18F60B	TO-247 or D^3
	0.29			24	APT23F60B	TO-247 or D^3
	0.22			30	APT28F60B	TO-247 or D^3
	0.19	36	APT34M60B	36	APT34F60B	TO-247
	0.15	45	APT43M60B2	45	APT43F60B2	T-MAX® or TO-264
	0.15	31	APT30M60J	31	APT30F60J	ISOTOP®
	0.11	60	APT56M60B2	60	APT56F60B2	T-MAX® or TO-264
	0.11	42	APT39M60J	42	APT39F60J	ISOTOP®
	0.09	70	APT66M60B2	70	APT66F60B2	T-MAX® or TO-264
	0.09	49	APT47M60J	49	APT47F60J	ISOTOP®
	0.055	84	APT80M60J	84	APT80F60J	ISOTOP®
500	0.39			15	APT15F50K	TO-220[K] or TO-220[KF]*
	0.30			20	APT20F50B	TO-247 or D^3
	0.24			24	APT24F50B	TO-247 or D^3
	0.19			30	APT30F50B	TO-247 or D^3
	0.15			37	APT37F50B	TO-247 or D^3
	0.13			43	APT42F50B	TO-247 or D^3
	0.10	56	APT56M50B2	56	APT56F50B2	T-MAX® or TO-264
	0.10	38	APT38M50J	38	APT38F50J	ISOTOP®
	0.075	75	APT75M50B2	75	APT75F50B2	T-MAX® or TO-264
	0.075	51	APT51M50J	51	APT51F50J	ISOTOP®
	0.062	84	APT84M50B2	84	APT84F50B2	T-MAX® or TO-264
	0.062	58	APT58M50J	58	APT58F50J	ISOTOP®
	0.036	103	APT100M50J	103	APT100F50J	ISOTOP®

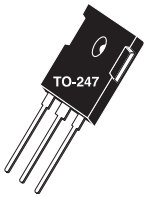
* Available on APT15F50K

Low Voltage Power MOS V® MOSFETs / FREDFETs

300	0.085	40	APT30M85BVRG	40	APT30M85BVFRG	TO-247
	0.070	48	APT30M70BVRG	48	APT30M70BVFRG	TO-247 or D^3
	0.040	70	APT30M40JVRG	70	APT30M40JVFRG	ISOTOP®
	0.019	130	APT30M19JVR	130	APT30M19JVFR	ISOTOP®
200	0.045	56	APT20M45BVRG	56	APT20M45BVFRG	TO-247
	0.038	67	APT20M38BVRG	37	APT20M38BVFRG	TO-247 or D^3 or T/R
	0.022	100	APT20M22B2VRG	100	APT20M22B2VFRG	T-MAX® or TO-264
	0.011	175	APT20M11JVR	175	APT20M11JVFR	ISOTOP®



TO-220[K] or TO-220[KF]*



TO-247[B]

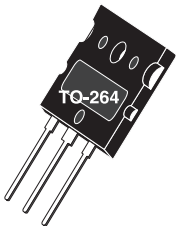


D^3 PAK[S]

Part Numbers for D^3 packages - replace "B" with "S" in part number

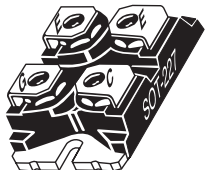


T-MAX®[B2]



TO-264[L]

Part Numbers for TO-264 packages - replace "B2" with "L" in part number



ISOTOP®[J]
SOT-227
(ISOLATED BASE)

Ultrafast, Low Gate Charge MOSFETs

FOR 250 kHz - 2 MHz SWITCHING APPLICATIONS

The Ultrafast, Low Gate Charge MOSFET family combines the lowest gate charge available in the industry with Microsemi's proprietary self-aligned aluminum metal gate structure. The result is a MOSFET capable of extremely fast switching speeds and very low switching losses. The metal gate structure and the layout of these chips provide an internal series gate resistance (EGR) an order of magnitude lower than competitive devices built with a polysilicon gate.

These devices are ideally suited for high frequency and pulsed high voltage applications.

Typical Applications:

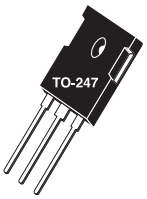
- Class D amplifiers up to 2 MHz
- High voltage pulsed DC
- AM transmitters
- Plasma deposition/etch

FEATURES:	BENEFITS:
• Series Gate Resistance (Rg) <0.1 ohm	• Fast switching, uniform signal propagation
• Tr and Tf times of <10ns	• Pulse power applications
• Industry's Lowest Gate Charge	• Fast switching, reduced gate drive power

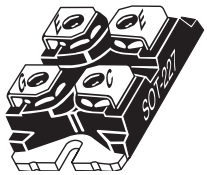
$BV_{(DSS)}$ Volts	$R_{DS(ON)}$ Max	I_D	MOSFET Part #	FREDFET Part #	Package Style
1200	4.700	3.5		APT1204R7KFLLG	T0-220
	4.700	3.5		APT1204R7BFLLG	T0-247 or D^3
	1.400	9		APT1201R4BFLLG	T0-247
	0.670	18	APT12067B2LLG		T-MAX®
	0.670	17	APT12067JLL		ISOTOP®
	0.570	22	APT12057B2LLG		T-MAX®
	0.570	19	APT12057JLL		ISOTOP®
1000	0.900	12	APT10090BLLG		T0-247
	0.780	14	APT10078BLLG		T0-247 or D^3
	0.450	23	APT10045B2LLG		T-MAX® or TO-264
	0.450	21	APT10045JLL		ISOTOP®
	0.350	28	APT10035B2LLG		T-MAX®
	0.350	25	APT10035JLL		ISOTOP®
	0.260	38		APT10026L2FLLG	TO-264 MAX
	0.260	30	APT10026JLL	APT10026JFLL	ISOTOP®
	0.210	37	APT10021JLL	APT10021JFLL	ISOTOP®
	0.140	52	APT8014L2LLLG	APT8014L2FLLG	TO-264 MAX
	0.110	51	APT8011JLL	APT8011JFLL	T-MAX™ or T0-264
800	0.200	38	APT8020B2LL		T-MAX®
	0.200	33	APT8020JLL		ISOTOP® or D^3 or T/R
500	0.140	35	APT5014BLLG		TO-247
	0.100	46	APT5010B2LLG	APT5010B2FLLG	T-MAX® or TO-264
	0.065	67	APT50M65B2LLG	APT50M65B2FLLG	T-MAX® or TO-264
	0.065	58	APT50M65JLLG	APT50M65JFLLG	ISOTOP®
	0.075	51	APT50M75JLL	APT50M75JFLL	ISOTOP®
	0.075	57	APT50M75B2LLG		T-MAX® or TO-264
	0.050	71	APT50M50JLL		ISOTOP®
	0.038	88	APT50M38JLL		ISOTOP®



T-MAX®[B2]



TO-247[B]



ISOTOP®[J]
SOT-227
(ISOLATED BASE)

COOLMOS
Power Semiconductors

COOLMOS™ MOSFETs

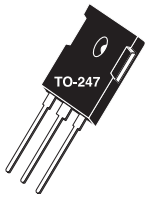
BV_{DSS} Volts	$R_{DS(ON)}$ Ohms	$I_{D(Cont)}$ Amps	Part Number	Package Style
	C3 TECHNOLOGY			
900	0.120	36	APT36N90BC3G	TO-247
800	0.450	11	APT11N80KC3G	TO-220
	0.450	11	APT11N80BC3G	TO-247
	0.145	34	APT34N80B2C3G	T-MAX® or TO-264
	0.145	34	APT34N80LC3G	TO-264
650	0.035	94	APT94N65B2C3G	T-MAX® or TO-264
	0.070	47	APT47N65BC3G	TO-247 or D^3
600	0.070	47	APT47N60BC3G	TO-247 or D^3
	0.035	77	APT77N60JC3	ISOTOP®
	0.042	94	APT94N60L2C3G	264-MAX™
	SERVER SERIES			
	0.045	60	APT60N60BCSG	TO-247 or D^3 or T/R
	NEW! C6 TECHNOLOGY			
600	0.041	77	APT77N60BC6	TO-247 or D^3
	0.070	53	APT53N60BC6	TO-247 or D^3
	0.099	38	APT38N60BC6	TO-247 or D^3
	0.125	30	APT30N60KC6	TO-220
	0.125	30	APT30N60BC6	TO-247 or D^3
	0.035	106	APT106N60B2C6	T-MAX™ or T0-264
650	0.041	85	APT97N65B2C6	T-MAX™ or T0-264
	0.035	94	APT94N65B2C6	T-MAX™



TO-220[K]



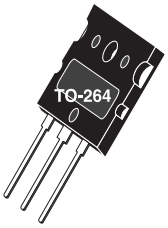
D^3 PAK[S]
TO-268



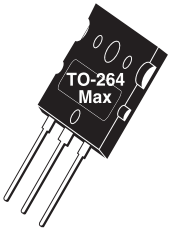
TO-247[B]



T-MAX®[B2]

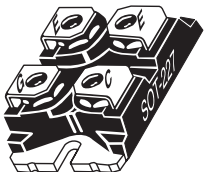


TO-264[L]



264-MAX™ [L2]

ISOTOP®[J]
SOT-227
(ISOLATED BASE)



"COOLMOS" comprise a new family of transistors developed by Infineon Technologies AG.
"COOLMOS" is a trademark of Infineon Technologies AG"

Linear MOSFETs

What is a Linear MOSFET?

A MOSFET specifically designed to be more robust than a standard MOSFET when operated with both high voltage and high current near DC conditions (>100msecs).

The Problem with SMPS MOSFETs

MOSFETs optimized for high frequency SMPS applications have poor high voltage DC SOA. Most SMPS type MOSFETs over-state SOA capability at high voltage on the data sheets. Above ~30V and DC conditions, SOA drops faster than is indicated by P_D limited operation.

For pulsed loads (t<10ms) there is generally no problem using a standard MOSFET.

Technology Innovation

Introduced in 1999, Microsemi modified its proprietary patented self-aligned metal gate MOSFET technology for enhanced performance in high voltage, linear applications. These Linear MOSFETs typically provide 1.5-2.0 times the DC SOA capability at high voltage compared to other MOSFET technologies optimized for switching applications.

Designers will need Linear MOSFETs when…

- High Current & > 200V >100msec
- Used as a variable power resistor
- Soft start application (limit surge currents)
- Linear amplifier circuit

Typical Applications…

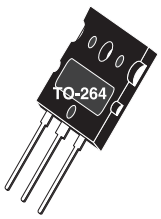
- Active loads above 200 volts such as DC dynamic loads for testing power supplies, batteries, fuel cells, etc.
- High voltage, high current constant current sources.

BV_{DSS} Volts	$R_{DS(ON)}$ Ohms	$I_{D(Cont)}$ Amps	SOA Watts	Part Number	Package Style
1000	0.600	18	325	APL1001J	
600	0.125	49	325	APL602B2G	
	0.125	43	325	APL602J	
500	0.090	58	325	APL502B2G	
	0.090	52	325	APL502J	

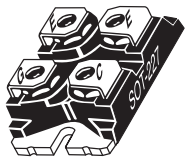
Part Numbers for TO-264 packages - replace "B2" with "L" in part number



T-MAX®[B2]



TO-264[L]



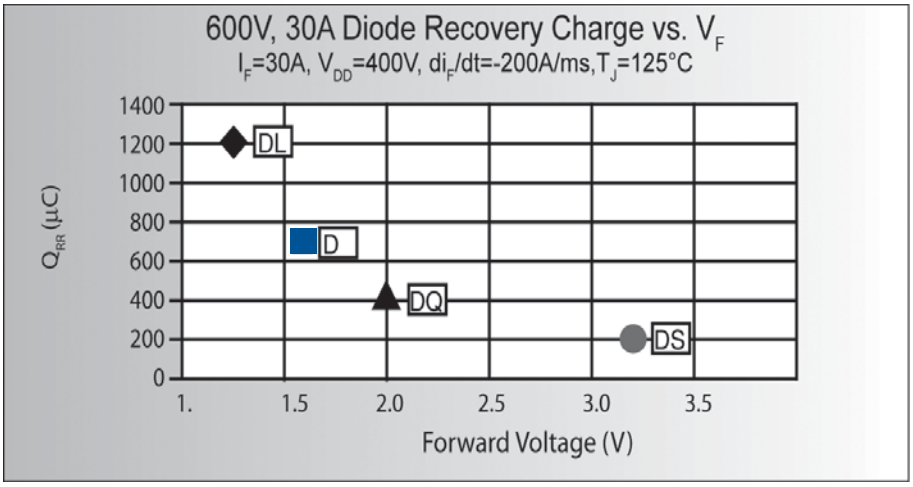
ISOTOP®[J]
SOT-227
(ISOLATED BASE)

Ultra Fast Recovery Diodes

Microsemi PPG offers five series of discrete diode products: a new DL series low VF ultra-soft recovery, the medium speed medium VF D series, the high speed DQ series, the very high speed DS series, and the silicon Schottky S series. These series of diodes are designed to provide high quality solutions to a wide range of high voltage, high power application requirements, ranging from fast recovery for continuous conduction mode power factor correction to low conduction loss for output rectification. Distinguishing features, technology used, and applications for each product family are summarized in the table below.

Series	Voltage Ratings	Features	Applications	Comment
DL	600	Low V_F Ultra-soft recovery Avalanche Rated	Output rectifier Resonant circuits	Ultra-soft recovery minimizes or eliminates snubber
D	200, 300, 400, 600, 1000, 1200	Medium V_F Medium Speed	Freewheeling Diode Output rectifier DC-DC converter	Proprietary platinum process
DQ	600, 1000, 1200	High speed Avalanche Rated	PFC Freewheeling Diode DC-DC converter	Stepped epi improves softness Proprietary platinum process
DS	600	Very high speed	High frequency PFC	Proprietary platinum process
Schottky	200	Low V_F Avalanche rated	Output rectifier Freewheeling Diode DC-DC converter	

The graph below shows the relative recovery speed and forward voltage positions of 600V DL, D, DQ and DS series diodes.



SIC SCHOTTKY Diodes

New!

SIC SCHOTTKY DIODES					
Volts	$I_{F(avg)}$ Amps	V_F volts Typ 25° C	Diode Series	Part Number	Package Style
SINGLE					
1200	10	1.5	SCD	APT10SCD120B	TO-247
	10	1.5	SCD	APT10SCD120K	TO-220
	20	1.5	SCD	APT20SCD120B	TO-247
	20	1.5	SCD	APT20SCD120S	D^3
	30	1.5	SCD	APT30SCD120B	TO-247
	30	1.5	SCD	APT30SCD120S	D^3
DUAL					
1200	10	1.5	SCD	APT10SCD120BCT	TO-247

Ultra Fast Recovery Diodes

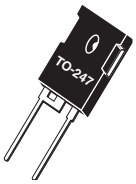
Volts	$I_{F(avg)}$ Amps	V_F (volts) Typ 25°C	t_{RR} (ns) Typ 25°C	Q_{RR} (nC) Typ 125°C at $I_F = I_F(avg)$	Diode Series	Part Number	Package Style
SINGLE	15	2.8	21	960	DQ	APT15DQ120BG	TO-247
	15	2.8	21	960	DQ	APT15DQ120KG	TO-220
	15	2.0	32	1300	D	APT15D120BG	TO-247
	15	2.0	32	1300	D	APT15D120KG	TO-220
	30	2.8	24	1800	DQ	APT30DQ120BG	TO-247
1200	30	2.8	24	1800	DQ	APT30DQ120KG	TO-220
	30	2.0	31	3450	D	APT30D120BG	TO-247
	40	2.8	26	2200	DQ	APT40DQ120BG	TO-247
	60	2.8	30	2800	DQ	APT60DQ120BG	TO-247
	60	2.0	38	4000	D	APT60D120BG	TO-247 or D^3
	75	2.8	32	3340	DQ	APT75DQ120BG	TO-247
	15	2.5	20	810	DQ	APT15DQ100BG	TO-247
	15	2.5	20	810	DQ	APT15DQ100KG	TO-220
	15	1.9	28	1550	D	APT15D100KG	TO-220
	30	2.5	22	1250	DQ	APT30DQ100BG	TO-247
1000	30	2.5	22	1250	DQ	APT30DQ100KG	TO-247
	30	1.9	29	2350	D	APT30D100BG	TO-247
	40	2.5	24	1430	DQ	APT40DQ100BG	TO-247
	60	2.5	29	2325	DQ	APT60DQ100BG	TO-247
	60	1.9	34	3600	D	APT60D100BG	TO-247 or D^3
	75	2.5	33	2660	DQ	APT75DQ100BG	TO-247
	15	2.0	16	250	DQ	APT15DQ60BG	TO-247
	15	2.0	16	250	DQ	APT15DQ60KG	TO-220
	15	1.6	21	520	D	APT15D60BG	TO-247
	15	1.6	21	520	D	APT15D60KG	TO-220
	30	2.0	19	400	DQ	APT30DQ60BG	TO-247
600	30	2.0	19	400	DQ	APT30DQ60KG	TO-220
	30	1.6	23	700	D	APT30D60BG	TO-247
	40	2.0	22	480	DQ	APT40DQ60BG	TO-247
	60	2.0	26	640	DQ	APT60DQ60BG	TO-247
	60	1.6	40	920	D	APT60D60BG	TO-247 or D^3
	75	2.0	29	650	DQ	APT75DQ60BG	TO-247
	100	1.25	45	3800	DL	APT100DL60BG	TO-247
400	30	1.3	22	360	D	APT30D40BG	TO-247
	60	1.3	30	540	D	APT60D40BG	TO-247
	30	1.1	21	150	D	APT30D20BG	TO-247
	30	0.83	25	448	Schottky	APT30S20BG	TO-247 or D^3
200	60	1.1	30	250	D	APT60D20BG	TO-247
	60	0.83	35	490	Schottky	APT60S20BG	TO-247 or D^3 or T/R
	100	0.89	40	690	Schottky	APT100S20BG	TO-247
TANDEM, DS DIODES FOR PFC BOOST APPLICATIONS							
600	15	3.2	13	85	DS	APT15DS60BG	TO-247
	30	3.2	17	180	DS	APT30DS60BG	TO-247
	(2, 300V Diodes Connected In Series)						



TO-220[K]



D^3 PAK[S]
TO-268



TO-247[B]

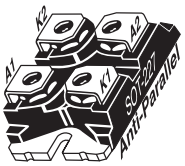


T-MAX®[B2]

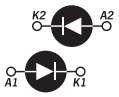
Part Numbers for D^3 packages - replace "B" with "S" in part number

Ultra Fast Recovery Diodes

Volts	$I_{F(avg)}$ Amps	V_F (volts) Typ 25°C	t_{RR}(ns) Typ 25°C	Q_{RR} (nC) Typ 125°C at $I_F = I_F$ (avg)	Diode Series	Part Number	Package Style
DUAL	2x27	2.0	31	3450	D	APT2X30D120J	
	2x30	2.6	25	1800	DQ	APT2X30DQ120J	
	2x53	2.0	38	4000	D	APT2X60D120J	
1200	2x60	2.5	30	2890	DQ	APT2X60DQ120J	
	2x93	2.0	47	5350	D	APT2X100D120J	
	2x100	2.4	45	5240	DQ	APT2X100DQ120J	
	2x28	1.9	29	2350	D	APT2X30D100J	
	2x55	1.9	34	3600	D	APT2X60D100J	
1000	2x60	2.2	30	2350	DQ	APT2X60DQ100J	
	2x95	1.9	43	4050	D	APT2X100D100J	
	2x100	2.1	45	3645	DQ	APT2X100DQ100J	
	2x30	1.8	20	400	DQ	APT2X30DQ60J	
	2x30	1.6	23	700	D	APT2X30D60J	
	2x60	1.7	27	650	DQ	APT2X60DQ60J	
600	2x60	1.6	40	920	D	APT2X60D60J	ISOTOP®
	2x100	1.6	30	980	DQ	APT2X100DQ60J	
	2x100	1.6	34	1450	D	APT2X100D60J	
	2x150	1.25	53	3800	DL	APT2X150DL60J	
	2x30	1.3	22	360	D	APT2X30D40J	
400	2x60	1.3	30	540	D	APT2X60D40J	
	2x100	1.3	37	1050	D	APT2X100D40J	
	2x100	1.0	40	3550	DL	APT2X101DL40J++	
300	2x100	1.2	36	650	D	APT2X101D30J	
	2x30	0.80	25	448	Schottky	APT2X31S20J	
200	2x60	0.83	35	490	Schottky	APT2X61S20J	
	2x100	1.1	39	840	D	APT2X100D20J	
	2x100	0.89	40	690	Schottky	APT2X101S20J	
1200	2x30	2.8	26	2100	DQ	APT30DQ120BCTG	TO-247 [BCT]
	2x15	2.5	20	810	DQ	APT15DQ100BCTG	TO-247 [BCT]
	2x15	1.9	28	1550	D	APT15D100BCTG	TO-247 [BHB]
	2x30	1.9	29	2360	D	APT30D100BCTG	TO-247 [BHB]
1000	2x30	1.9	30	2350	D	APT30D100BHBG	TO-247 [BCA]
	2x60	2.5	29	2325	DQ	APT60DQ100LCTG	TO-264 [LCT]
	2x60	1.9	35	3600	D	APT60D100LCTG	TO-264 [LCT]
	2x15	1.6	21	520	D	APT15D60BCTG	T0-247
	2x15	2.0	15	250	DQ	APT15DQ60BCTG	TO-247 [BCT]
	2x15	1.6	20	520	D	APT15D60BCAG	TO-247 [BCA]
	2x30	2.0	22	480	DQ	APT30DQ60BHBG	TO-247 [BHB]
	2x30	2.0	19	400	DQ	APT30DQ60BCTG	TO-247 [BCT]
600	2x30	1.6	23	700	D	APT30D60BCTG	TO-247 [BCT]
	2x30	1.6	25	700	D	APT30D60BHBG	TO-247 [BHB]
	2x30	1.6	25	700	D	APT30D60BCAG	TO-247 [BCA]
	2x40	2.0	22	480	DQ	APT40DQ60BCTG	TO-247 [BCT]
	2x60	2.0	26	640	DQ	APT60DQ60BCTG	TO-247 [BCT]
	2x60	1.6	30	920	D	APT60D60LCTG	TO-264 [LCT]
400	2x30	1.3	22	360	D	APT30D40BCTG	TO-247 [BCT]
	2x60	1.3	30	540	D	APT60D40LCTG	TO-264 [LCT]
300	2x30	1.2	25	1300	D	APT30D30BCTG	TO-247 [BCT]
	2x30	1.1	21	150	D	APT30D20BCTG	TO-247 [KCT]
	2x30	1.1	21	150	D	APT30D20BCAG	TO-247 [BCA]
	2x30	0.80	25	448	Schottky	APT30S20BCTG	TO-247 [BCT]
200	2x60	0.83	35	490	Schottky	APT60S20B2CTG	T-MAX® [B2CT]
	2x100	0.89	40	690	Schottky	APT100S20LCTG	TO-264[LCT]

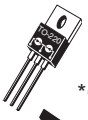


ISOTOP®[J] SOT-227
Antiparallel
Configuration
(ISOLATED BASE)

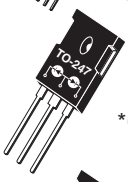


Part Numbers for Parallel Configuration replace 30, 60, or 100 with 31, 61, or 101. Except Schottky

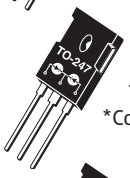
Example: 2X30D120J becomes 2X31D120J



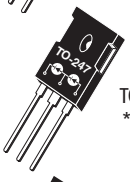
TO-220[KCT]
*Common Cathode



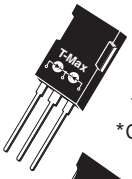
TO-247[BCA]
*Common Anode



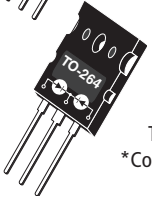
TO-247[BCT]
*Common Cathode



TO-247[BHB]
*Half Bridge



T-MAX® [B2CT]
*Common Cathode



TO-264[LCT]
*Common Cathode

*Current ratings per leg ++ Parallel Form Only

Datasheets available on www.microsemi.com

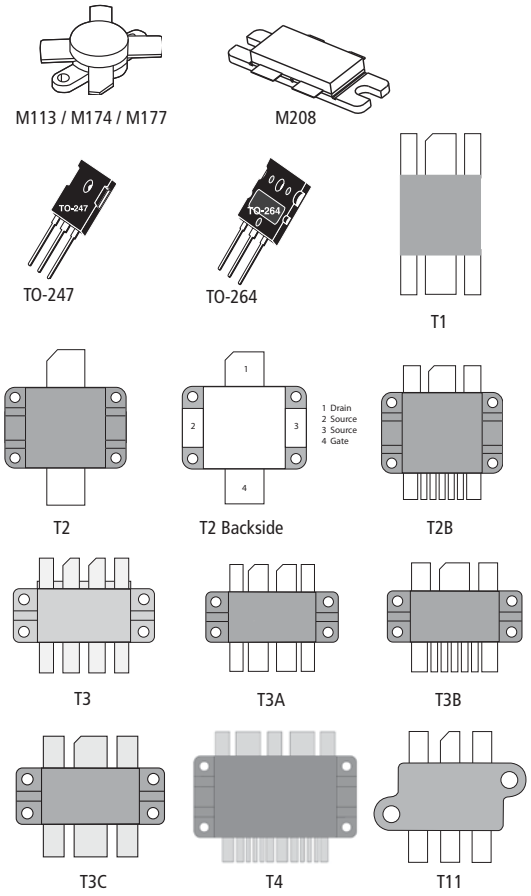
All Products RoHS Compliant

High Voltage RF MOSFETs

The ARF family of RF Power MOSFETs are optimized for applications requiring frequencies as high as 150MHz and operating voltages as high as 400V. Historically, RF Power MOSFETs were limited to applications of 50V or less. This limitation has been removed by combining Microsemi's high voltage MOSFET technology with RF specific die geometries.

Why Higher Voltage? Higher V_{DD} means higher load impedance. For 150W output from a 50V supply the load impedance is only 8 ohms. At 125V, the load impedance is 50 ohms. The higher impedance allows simpler transformers and combiners. Paralleled devices can still operate into reasonable and convenient impedances. The increased operating voltage also lowers the DC current required for any given power output increasing efficiency and reducing the size, weight and cost of other system components.

Pout (W)	Freq. (MHz)	V_{DD}/BV_{DSS} (V)	θJC (°C/W)	Package Style	Part Number	Class of Operation
90	120	150V/450V	0.76	TO-247	ARF449AG/BG	C-E
100	100	125V/500V	0.70	TO-247	ARF463AG/BG	A-E
	100	125V/500V	0.70	TO-247	ARF463AP1G/BP1G	A-E
140	65	250V/900V	0.55	TO-247	ARF446G	C-E
	65	250V/900V	0.55	TO-247	ARF447G	C-E
	65	150V/450V	0.55	TO-247	ARF448AG/BG	C-E
150	65	125V/500V	0.50	TO-247	ARF460AG/BG	A-E
	65	250V/1kV	0.50	TO-247	ARF461AG/BG	A-E
	60	300V/1.2kV	0.50	TO-247	ARF465AG/BG	A-E
150	150	165V/500V	0.60	M174	ARF521	A-E
300	150	165V/500V	0.35	M208	ARF473	A-E
	150	165V/500V	0.31	T3A	ARF475FL	A-E
	150	165V/500V	0.31	T3C	ARF476FL	A-E
300	45	200V/1kV	0.35	TO-264	ARF466AG/BG	A-E
	45	200V/1kV	0.13	T3	ARF466FL	A-E
400	65	165V/500V	0.18	T3C	ARF477FL	A-E
750	25	250V/1000V	0.13	T2	ARF1519	A-E
750	40	125V/500V	0.12	T1	ARF1500	A-E
	40	250V/1kV	0.12	T1	ARF1501	A-E
	40	300V/1.2kV	0.12	T1	ARF1505	A-E
750	40	400V/1000V	0.12	T1	ARF1510	D
	40	380V/500V	0.12	T1	ARF1511	D



Drivers and Driver-RF MOSFET Hybrids

The DRF1200/01/02/03 Hybrids integrates Driver, bypass capacitors and RF MOSFETS into a single package. Integration maximizes amplifier performance by minimizing transmission line parasitics between the Driver and MOSFET. The DRF1300 or DRF1301 has two independent channels, each containing a Driver and RF MOSFET in a push pull configuration. The DRF1400A and B are half bridge hybrids with symmetrically orientated leads so that the two can easily be configured into a full bridge converter. All DRF parts feature a proprietary Anti-ring function to eliminate cross conduction in a Bridge or push-pull topologies. All DRF parts can be externally selected in either an inverting or non-inverting configuration.

P_D (W)	Freq. (MHz)	V_{DD}/BV_{DSS} (V)	θJC (°C/W)	Package Style	Part Number	Class of Operation	Description
600	30	15V/1000V	1.00	T2B	DRF1200	D-E	Driver and High Voltage RF MOSFET
1060	30	15V/1000V	.025	T2B	DRF1201	D-E	Driver and High Voltage/High Power RF MOSFET
1060	30	15V/500V	.025	T2B	DRF1202	D-E	Driver and High Power RF MOSFET
600	30	15V/1000V	0.09	T2B	DRF1203	D-E	Driver and High Voltage RF MOSFET
1000	30	15V/500V	0.06	T4	DRF1300	D-E	2 Drivers/RF MOSFETs in Push-Pull Configuration
1000	30	15V/1000	0.06	T4	DRF1301	D-E	2 Drivers/RF MOSFETs in Push-Pull Configuration
1500	30	15V/500	0.06	T4	DRF1400	D-E	2 Drivers/RF MOSFETs in a H Bridge Configuration

High Frequency RF MOSFETs

The VRF family of RF MOSFETs are improved replacements for industry standard RF transistors. They provide improved ruggedness by increasing the BV_{DSS} over 30% from the industry standard of 125 volts to 170V minimum. Low cost flangeless packages are another improvement that show Microsemi's dedication to optimizing performance, reducing cost and improving reliability. We will continue to offer a greater number of product offerings in the new reduced-cost flangeless packages.

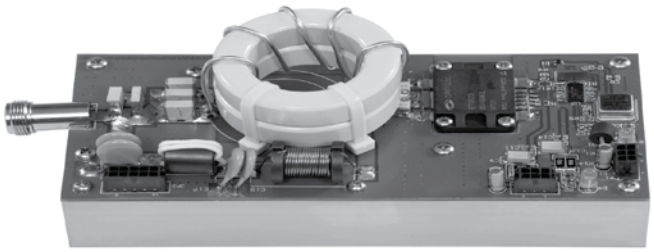
Pout Min (W)	Freq. (MHz)	Gain Typ (dB)	η Typ (%)	V_{DD}/BV_{DSS} (V)	Coss Typ (pF)	VSWR Load	θJC (°C/W)	Case Style	Part Number
150	175	13	45	28V/80V	375	30:1	0.60	M174	VRF141
30	175	16	50	50V/170V	40	30:1	1.52	M113	VRF148A
150	150	11	50	50V/170V	210	30:1	0.60	M174	VRF150
150	175	14	50	50V/170V	200	30:1	0.60	M174	VRF151
300	175	14	55	28/80	375	5:1	0.35	M208	VRF141G
300	175	16	55	50V/170V	200	5:1	0.35	M208	VRF151G
150	175	14	50	50V/130V	215	30:1	0.60	M174	VRF152
600	30	17	45	50V/170V	775	-	0.13	T2	VRF154FL
600	30	21	45	50V/170V	810	-	0.13	T2	VRF157FL
300	30	21	50	50V/170V	400	3:1	0.27	M177	VRF2933

Reference Design Kits

DRF1200/CLASS-E, 13.56 MHz

DRF1200/CLASS-E, 27.12 MHz

The DRF1200/CLASS-E Single Ended RF Generator is a reference design providing the designer the ability to evaluate an 85% efficient 1000W CLASS-E RF Generator



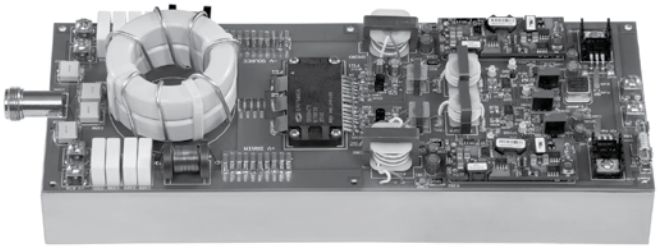
DRF1300/CLASS-D, 13.56 MHz

The DRF1300/CLASS-D Push Pull RF Generator is a reference design providing the designer the ability to evaluate an 80% efficient 2000W CLASS-D RF Generator



DRF1400/CLASS-D, 13.56 MHz

The DRF1400/CLASS-D Half Bridge RF Generator is a reference design providing the designer the ability to evaluate an 85% efficient 2500W CLASS- D RF Generator



All kits include: A fully populated board attached to an aluminum heat sink. An extensive application note explaining the theory of operation with desginers recommendations for evaluation and board layout. All key waveforms are illustrated and described. A complete parts list with recommended vendor part numbers and the board's Gerber file are provided for an easy transition into an end application.

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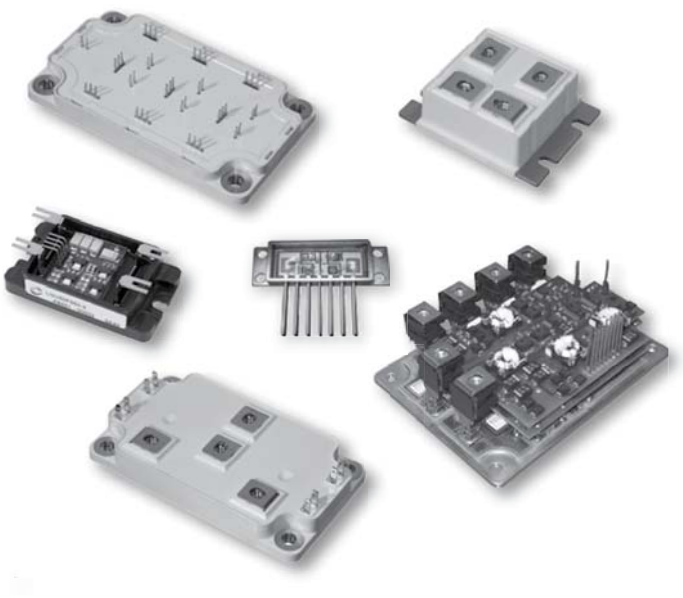
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Microsemi combines a formidable array of technologies in semiconductors, packaging and automated manufacturing to produce a wide range of high quality modules optimized for:

- Reliability
- Efficiency and electrical performance
- Low cost
- Space savings
- Reduced assembly time

The readily available standard module product line spans a wide selection of circuit toplogies, semiconductors including Silicon Carbide, voltage and current ratings and packages. If you need even more flexibility or intellectual property protection, Microsemi can often customize a standard module with low set up cost and with a short lead time. Unique requirements can be met with Application Specific Power Modules (ASPM®).

Microsemi serves a broad spectrum of industrial applications for Welding, Solar, Induction Heating, Medical, UPS, Motor Control and SMPS markets as well as HI-REL applications for Semicap, Defense and Aerospace markets. A wide selection of construction materials enables Microsemi to manufacture with short lead times modules that feature:

- Extended temperature range: -60°C to +200°C
- High reliability
- Reduced size and weight
- Hi-Rel testing and screening options

Microsemi's experience and expertise in power electronic conversion brings the most effective technical support for your new development.

- Isolated gate driver
- Snubbers
- Mix & match semiconductors
- Short circuit protection
- Temperature & current sensing
- Parameter binning

Standard Electrical Configurations

Microsemi PMP offers a wide range of standard electrical configurations housed in various packages and capable to respond to many power conversion demands asking for high power density and performance. Same topology can be offered with different semiconductors type.

Electrical Topology	IGBT 600V to 1700V	MOSFET 75V to 1200V	Diode 30V to 1700V	Mix Si-SiC 600 & 1200V	Full SiC 600 & 1200V
Asymmetrical Bridge	X	X			
Boost Buck	X	X			
Boost & Buck Chopper	X	X		X	X
Common Anode			X		
Common Cathode			X		
Dual Boost & Buck Chopper	X	X		X	
Dual Common Source	X	X			
Dual Diode					X
Full Bridge	X	X	X		X
Full Bridge + PFC	X	X		X	
Full Bridge + Secondary Fast Rectifier Bridge	X	X		X	
Full Bridge + Series and Parallel Diodes		X		X	
Interleaved PFC	X	X			
Linear single and Dual switch		X			
Phase Leg	X	X	X		X
Phase Leg Intelligent	X				
Phase Leg + PFC		X		X	
Phase Leg + Series and Parallel Diodes		X		X	
Single Switch	X	X	X		
Single Switch + Series and Parallel Diodes		X		X	
Single Switch + Series Diodes	X	X			
3-Level NPC Inverter	X				X
3-Level T-Type Inverter	X			X	
3-Phase Bridge	X		X		
Triple Dual Common Soure	X	X			
Triple Phase Leg	X	X		X	
	NPT Trench3 Trench4 Trench4 Fast	MosFET FredFET CoolMOS	Schottky FRED Std Rectifier Thyristor	IGBT MosFET Diode	Diode MosFET

Packaging

Improved Low Profile Packages

SP1 (12mm)
SP3 (12mm)
SP4 (17mm)
SP6 (17mm)
SP6-P (12mm)


SP1


SP3F


SP3


SP4


SP6


SP6-P

Industry Standard Packages

SOT-227 (Isotop®)
SP2 (17mm)
34mm & 62mm Types
D1 (34 mm Wide)
D3 (62 mm Wide)
D4 (62 mm Wide)


SOT-227


SP2


D1


D3


D4


SD1


SD2


SM1


SM2


SM2-1


SM3


SM3-1


SM4


SM5


SF1


Mini-Mod Surface Mount


Mini-Mod


TO-249

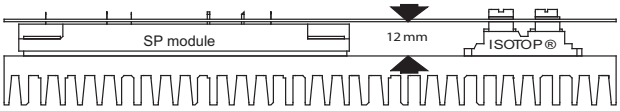

9-pin TO-249


Twin Tower


VJ


Half Pack

Package Advantages





SP1 package:

-Replaces 2 SOT-227 parts
-Improved assembly time and cost
-Height compatible with SOT-227
-Copper base plate



SP3F package:

-Replaces up to 4 SOT-227 parts
-Reduced assembly time and cost
-Height compatible with SOT-227
-Copper base plate


30 mm


17 mm

SP6 package:

Offers the same footprint and the same pinout location as the popular 62mm package but with lower height, leading to:
- Reduced stray inductance
- Reduced parasitic resistance
- Higher efficiency at high frequency



SP6-P package:

-Replaces up to 6 SOT-227 parts
-Height compatible with SOT-227
-Low inductance solder pins
-High current capability

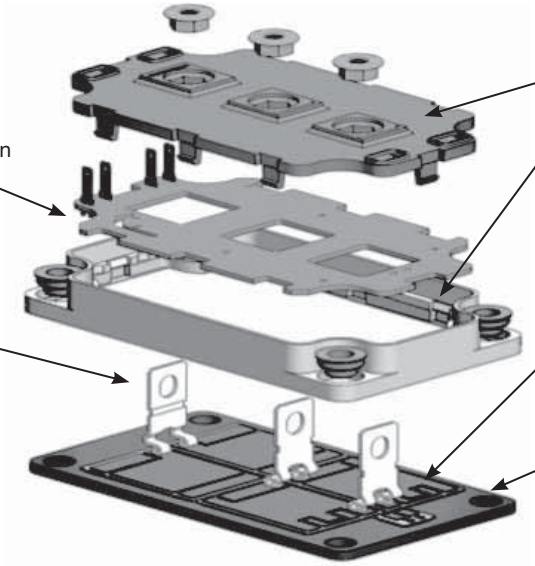
Custom Power Modules

Microsemi PMP has created the Application Specific Power Module (ASPM) concept and has been offering customized power modules since 1983. Microsemi PMP offers a complete engineered solution with mix and match capabilities in term of package, configuration, performance and cost.

Internal Printed Circuit Board
Not available in all modules.
Used to route gate signals tracks to small signal terminals
Used to mount gate circuit and protection in case of intelligent power module

Terminals
Screw on or Solder pins
Provides the user with power and signal connections with minimum parasitic resistance and inductance

Substrates
Al2O3, AlN, Si3N4
Provide isolation and good heat transfer to the base plate



Package
Standard or Custom
Ensure environmental protection and mechanical robustness

Power Semiconductor Die
IGBT, Mosfet, Diode, SiC, Thyristor, Switching devices soldered to the substrates and connected by ultrasonic Al wire bonds

Base Plate
Improve the heat transfer to the heat sink
Copper for good thermal transfer
AlSiC, CuW, CuMoCu for improved reliability

3 levels of customization are proposed offering different cost and low volume entry:

Change Options:	Die	Substrate	Base plate	Plastic lid	Terminals	NRE level	MOQ
Elect./thermal performance	Die P/N	Material	Material	-	-	None to low	5 to 10 pieces
Elect./thermal performance + electrical configuration	Die P/N	Material & Layout	Material	-	-	Low to medium	
Elect./thermal performance + electrical configuration + module housing	Die P/N	Material & Layout	Material & Shape	Material & Shape	Shape	Medium to high	

Microsemi PMP power modules are made of different sub-elements. Most of them are standard and can be re-used to build infinite solutions for the end user.

Microsemi PMP offers optimum development cost and cycle time thanks to long term experience and wide range of available technologies.

Power Modules Features	Customer Benefits
High Power Density	Size and cost reduction
Isolated and highly thermally conductive substrate	Excellent thermal management
Internal wiring	Reduced external hardware
Minimum parasitics	Improved performance
Minimum output terminals	Reduced assembly time
Mix & match components	Optimizes losses
Full engineered solutions	Easy upgrade/less parts counts/short time to market/IP protection

FLEXIBILITY

Great level of integration
Mix of Silicon within the same package
No quantity limitation

PACKAGING CAPABILITY

Standard and custom packages
Standard and custom terminals
Various substrate technologies

TECHNOLOGY

Application oriented

RELIABILITY

Coefficient of thermal expansion matching

APPLICATIONS

Solar - Welding - Plasma Cutting - Semicap - MRI & Xray - EV/HEV - Induction Heating - UPS - Motor control - Data Communication

Rugged Custom Power Modules

Microsemi PMP has acquired a great experience and know-how in module customization to address rugged and wide temperature range application and offers solution to meet with next generation integrated power systems expectation in terms of:

- Improved Reliability
- Wider Operating Temparatures
- Higher Power
- Higher Efficiency
- Lower Weight and Size
- Lower Cost

Applications

- Avionics actuation system
- Avionics lift and pump
- Military ground vehicule
- power supply and motor control
- Navy ship auxiliary power supply
- Down hole drilling

Test Capabilities

- X-rays inspection
- Dielectric test (up to 6KV)
- Electrical testing at specified temperature
- Burn-in
- Acoustic imaging

Reliability Testing Capabilities

- Power cycling
- Hermetic sealing
- Moisture
- Salt atmosphere
- HTGB
- Temperature shock
- HAST
- H3TRB
- Altitude
- Mechanical shock, vibration

Expertise Capabilities

- Cross-sectioning
- Structural analysis

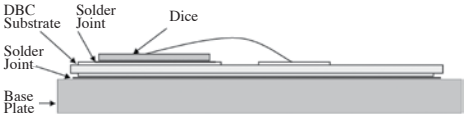
All tests can be conducted upon demand by sampling or at 100%. Tests performed in house or with external lab.

Our Core Competencies

- Extensive experience of rugged solutions for harsh environments
- Wide range of Silicon technologies
- Wafer fab capabilities
- Mix of assembly technologies
- Hermetic and robust plastic packages
- Custom test & burn-in solutions
- ISO9001 certified
- End-of-life (obsolescence) management
- Thermal management
- Material expertise
- Product life management associated to risks analysis

Various solutions are proposed offering different cost and low volume of entry:

	Industrial Application	Extended Temperature Application	Harsh Environment Application	
Standard Module	X			No NRE Low Volume Entry
Modified Standard	X	X		Low NRE Low Volume Entry
Custom Module	X	X	X	Medium to High NRE Low Volume Entry



	CTE (ppm/K)	Thermal conductivity (W/m.K)	Rthjc (K/W)
Silicon Die (120 mm2)	4	136	
Cu/Al_2O_3	17/7	390/25	0.35
$AlSiC/Al_2O_3$	7/7	170/25	0.38
Cu/AlN	17/5	390/170	0.28
AlSiC/AlN	7/5	170/170	0.31
$AlSiC/Si_3N_4$	7/3	170/60	0.31

	Material	CTE (ppm/K)	Thermal conductivity (W/m.K)	Density (g/cc)
Base plate	CuW AlSiC Cu	6.5 7 17	190 170 390	17 2.9 8.9
Substrate	Al_2O_3 AlN Si_3N4	7 5 3	25 170 60	- - -
Die	Si SiC	4 2.6	136 270	- -

Module performance and reliability depends on the choice of the assembly materials

More closely matched materials TCE's increase the module life time because it will result in much less stress at the interface of the materials and inside the materials.

The higher the thermal conductivity, the lower is the junction to case thermal resistance and the lower will be the delta of junction temperature of the device during operation such that the effect of power cycling on the dice will be minimized.

Another important feature is the material density particularly for the baseplate. Taking copper as the reference, Alsic has a density of 1/3 while Cuw has twice the density. Therefore AlSiC will provide substantial weight reduction at the same time as reliability increase.







Power Module Part Numbering System

IGBT Modules

APT	GL	475	A	120	T	D3	G
I	II	III	IV	V	VI	VII	VIII

I — **Trade Mark**

II — **IGBT Type:**
GF = NPT or NPT FAST
GFQ = NPT ULTRA FAST
GL = TRENCH 4
GT = TRENCH 3
GV = Mix NPT/TRENCH
CV = Mix TRENCH/CoolMOS

III — **Current**:
Ic @ Tc=80°C

IV — **Topology:**
A = Phase Leg
BB = Boost Buck
DA = Boost Chopper
DDA = Double Boost Chopper
DH = Asymmetrical Bridge
DSK = Double Buck Chopper
DU = Dual Common Source
H = Full Bridge
HR = T-Type 3-Level
SDA = Double Boost + Bypass Diode
SK = Buck Chopper
TA = Triple Phase Leg
TDU = Triple Dual Common Source
TL = Three Level
U = Single Switch
VDA = Interleaved PFC
X = Three Phase Bridge

V — **Blocking Voltage:**
60 = 600V
120 = 1200V
170 = 1700V

VI — **Option:**
A = AIN Substrate
C = SiC Diode
D = Series Diode
T = Temperature Sensor
W = Clamping Parallel Diode

VII — **Package:**
1 = SP1
2 = SP2
3 = SP3
P = SP6-P
D1 = D1 (34mm)
D3 = D3 (62mm)
D4 = D4 (62mm)

VIII — **G** = RoHS Compliant

MOSFET Modules

APT	C	60	DA	M24	T	1	G
I	II	III	IV	V	VI	VII	VIII

I — **Trade Mark**

II — **MOSFET Type:**
MC = MOSFET SiC
M = MOSFET
C = CoolMOS

III — **Blocking Voltage:**
08 = 75V
10 = 100V
20 = 200V
50 = 500V
60 = 600V
80 = 800V
90 = 900V
100 = 100V
120 = 120V

IV — **Topology:**
A = Phase Leg
BB = Boost Buck
DA = Boost Chopper
DDA = Double Boost Chopper
DH = Asymmetrical Bridge
DSK = Double Buck Chopper
DU = Dual Common Source
H = Full Bridge
HR = T-Type 3-Level
SDA = Double Boost + Bypass Diode
SK = Buck Chopper
TA = Triple Phase Leg
TDU = Triple Dual Common Source
TL = Three Level NPC
U = Single Switch
VDA = Interleaved PFC

V — **RDSON @ Tc=25°C**
240 = 2400mΩ
24 = 240mΩ
M24 = 24mΩ

VI — **Option:**
A = AlN Substrate
C = SiC Diode
D = Series Diode
F = FREDFET
S = Series and Parallel Diodes
T = Temperature Sensor
U = Ultrafast FREDFET

VII — **Package:**
1 = SP1
2 = SP2
3 = SP3
P = SP6-P

VIII — **G** = RoHS Compliant

Diode Modules

APT	DR	90	X	160	1	G
I	II	III	IV	V	VI	VII

I — **Trade Mark**

II — **Diode Type:**
DF = FRED
DR = Standard Rectifier
DC = SiC
DSK = Schottky

III — **Current:**
IF @ Tc=80°C

IV — **Topology:**
AA = Dual Common Anode
BB = Boost Buck
AK = Dual Series
KK = Dual Common Cathode
H = Single Phase Bridge
U = Single Switch
X = Three Phase Bridge

V — Blocking Voltage:
20 = 200V
40 = 400V
60 = 600V
100 = 1000V
120 = 1200V
160 = 1600V
170 = 1700V

VI — **Package:**
1 = SP1
3 = SP3

VII — **G** = RoHS Compliant

Optional Materials

Optional materials are available upon demand on most of the listed standard power modules. Options are indicated with a letter in the suffix of the module part number. Temperature Sensor Option is indicated in the catalog with "YES" or "option" when available on standard part or on demand.

- **A** AIN Substrate for higher thermal conductivity
- **M** AlSiC Base plate material for improved temperature cycling capabilities
- **T** Temperature Sensor (NTC or PTC) for Case Temperature information
- **C** SiC Diode for higher efficiency
- **N** Si3N4 Substrate
- **E** Press fit terminals (for SP3 package only)

IGBT Power Modules

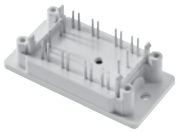
CHOPPER AND PHASE LEG

V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	…DA… or …U2	…SK… or …U3	…A…	
600	NPT	250	2.1	D3	option	APTGF250DA60D3G	APTGF250SK60D3G	APTGF250A60D3G	
		330	2.1	D3	option	APTGF330DA60D3G	APTGF330SK60D3G	APTGF330A60D3G	
	NPT FAST	30	2.1	SOT227	-	APT30GF60JU2	APT30GF60JU3	N/A	
		30	2.1	SP1	YES	N/A	N/A	APTGF30A60T1G	
		50	2.1	SOT227	-	APT50GF60JU2	APT50GF60JU3	N/A	
		60	2.1	SOT227	-	APT60GF60JU2	APT60GF60JU3	N/A	
		90	2.1	SP1	YES	APTGF90DA60T1G	APTGF90SK60T1G	APTGF90A60T1G	
		100	2.1	SOT227	-	APT100GF60JU2	APT100GF60JU3	N/A	
		150	2.1	SP3	YES	N/A	N/A	APTGF150A60T3AG	
		165	2.1	D1	-	APTGF165DA60D1G	APTGF165SK60D1G	APTGF165A60D1G	
		180	2.1	SP4	YES	APTGF180DA60TG	APTGF180SK60TG	APTGF180A60TG	
		350	2.1	SP6	option	APTGF350DA60G	APTGF350SK60G	APTGF350A60G	
	TRENCH3	75	1.5	SP1	YES	APTGT75DA60T1G	APTGT75SK60T1G	APTGT75A60T1G	
		100	1.5	SP1	YES	APTGT100DA60T1G	APTGT100SK60T1G	APTGT100A60T1G	
		100	1.5	SP2	-	N/A	N/A	APTGT100A602G	
		150	1.5	SP1	YES	APTGT150DA60T1G	APTGT150SK60T1G	APTGT150A60T1G	
		150	1.5	SP3	YES	N/A	N/A	APTGT150A60T3AG	
		200	1.5	SP2	-	N/A	N/A	APTGT200A602G	
		200	1.5	SP3	YES	APTGT200DA60T3AG	APTGT200SK60T3AG	APTGT200A60T3AG	
		300	1.5	SP4	YES	N/A	N/A	APTGT300A60TG	
		300	1.5	SP6	option	APTGT300DA60G	APTGT300SK60G	APTGT300A60G	
		300	1.5	D3	option	APTGT300DA60D3G	APTGT300SK60D3G	APTGT300A60D3G	
		400	1.5	D3	option	APTGT400DA60D3G	APTGT400SK60D3G	APTGT400A60D3G	
		450	1.5	SP6	option	APTGT450DA60G	APTGT450SK60G	APTGT450A60G	
		600	1.5	SP6	option	APTGT600DA60G	APTGT600SK60G	APTGT600A60G	
650	TRENCH 4 FAST	100	1.85	SP1	YES	N/A	N/A	APTGLQ100A65T1G	***NEW!***
		600	1.85	SP6	YES	N/A	N/A	APTGLQ600A65T6G	***NEW!***
1200	NPT FAST	15	3.2	SP1	YES	N/A	N/A	APTGF15A120T1G	
		50	3.2	SP1	YES	APTGF50DA120T1G	APTGF50SK120T1G	APTGF50A120T1G	
		75	3.2	SP1	YES	APTGF75DA120T1G	N/A	N/A	
		100	3.2	SP1	YES	APTGF100DA120T1G	N/A	N/A	
		100	3.2	SP2	-	N/A	N/A	APTGF100A1202G	
		100	3.2	SP3	YES	N/A	N/A	APTGF100A120T3AG	
		100	3.2	SP4	YES	APTGF100DA120TG	APTGF100SK120TG	APTGF100A120TG	
		150	3.2	SP3	YES	N/A	N/A	APTGF150A120T3AG	
		150	3.2	SP4	YES	APTGF150DA120TG	APTGF150SK120TG	APTGF150A120TG	
		200	3.2	D3	option	N/A	N/A	APTGF200A120D3G	
		300	3.2	SP6	option	APTGF300DA120G	APTGF300SK120G	APTGF300A120G	
		300	3.2	D3	option	APTGF300DA120D3G	APTGF300SK120D3G	APTGF300A120D3G	
	TRENCH 3	35	1.7	SP1	YES	N/A	N/A	APTGT35A120T1G	
		35	1.7	SOT227	-	APT35GT120JU2	APT35GT120JU3	N/A	
		50	1.7	SOT227	-	APT50GT120JU2	APT50GT120JU3	N/A	
		50	1.7	SP1	YES	N/A	N/A	APTGT50A120T1G	
		50	1.7	SP2	-	N/A	N/A	APTGT50A1202G	
		50	1.7	SP4	YES	APTGT50DA120TG	APTGT50SK120TG	N/A	
		75	1.7	SOT227	-	APT75GT120JU2	APT75GT120JU3	N/A	
		75	1.7	SP1	YES	N/A	N/A	APTGT75A120T1G	

continued next page


SOT-227


SP1


SP2


SP3


SP4


SP6

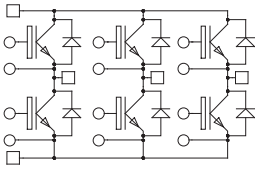

D1


D3

IGBT Power Modules

CHOPPER AND PHASE LEG CONT.

V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	…DA… or …U2	…SK… or …U3	…A…	
1200	TRENCH 3	75	1.7	SP2	-	N/A	N/A	APTGT75A1202G	
		75	1.7	SP4	YES	APTGT75DA120TG	APTGT75SK120TG	N/A	
		100	1.7	SP1	YES	APTGT100DA120T1G	N/A	N/A	
		100	1.7	SOT227	-	APT100GT120JU2	APT100GT120JU3	N/A	
		100	1.7	D1	-	N/A	N/A	APTGT100A120D1G	
		100	1.7	SP2	-	N/A	N/A	APTGT100A1202G	
		100	1.7	SP3	YES	N/A	N/A	APTGT100A120T3AG	
		100	1.7	SP4	YES	N/A	N/A	APTGT100A120TG	
		150	1.7	SP6	option	APTGT150DA120G	APTGT150SK120G	APTGT150A120G	
		150	1.7	D1	-	APTGT150DA120D1G	APTGT150SK120D1G	APTGT150A120D1G	
		150	1.7	SP2	-	N/A	N/A	APTGT150A1202G	
		150	1.7	SP3	YES	N/A	N/A	APTGT150A120T3AG	
		150	1.7	SP4	YES	N/A	N/A	APTGT150A120TG	
		200	1.7	SP6	option	APTGT200DA120G	APTGT200SK120G	APTGT200A120G	
		200	1.7	D3	option	APTGT200DA120D3G	APTGT200SK120D3G	APTGT200A120D3G	
		300	1.7	SP6	option	APTGT300DA120G	APTGT300SK120G	APTGT300A120G	
		300	1.7	D3	option	APTGT300DA120D3G	APTGT300SK120D3G	APTGT300A120D3G	
		400	1.7	SP6	option	APTGT400DA120G	APTGT400SK120G	APTGT400A120G	
		400	1.7	D3	option	N/A	N/A	APTGT400A120D3G	
	TRENCH 4	40	1.85	SOT227	-	APT40GL120JU2	APT40GL120JU3	N/A	
		90	1.85	SP1	YES	APTGL90DA120T1G	APTGL90SK120T1G	APTGL90A120T1G	
		180	1.85	SP2	-	N/A	N/A	APTGL180A1202G	
		180	1.85	SP3	YES	N/A	N/A	APTGL180A120T3AG	
		325	1.85	D3	option	APTGL325DA120D3G	APTGL325SK120D3G	APTGL325A120D3G	
		475	1.85	D3	option	APTGL475DA120D3G	APTGL475SK120D3G	APTGL475A120D3G	
		700	1.85	D3	option	APTGL700DA120D3G	APTGL700SK120D3G	N/A	
	TRENCH 4 FAST	100	2.05	SP3	YES	N/A	N/A	APTGLQ100A120T3AG	***NEW!***
		400	2.05	SP6	YES	N/A	N/A	APTGLQ400A120T6G	***NEW!***
1700	TRENCH 3	30	2.0	SP1	YES	APTGT30DA170T1G	APTGT30SK170T1G	APTGT30A170T1G	
		50	2.0	SP1	YES	APTGT50DA170T1G	APTGT50SK170T1G	APTGT50A170T1G	
		50	2.0	SP4	YES	APTGT50DA170TG	APTGT50SK170TG	APTGT50A170TG	
		75	2.0	SP1	YES	APTGT75DA170T1G	N/A	N/A	
		75	2.0	D1	-	APTGT75DA170D1G	APTGT75SK170D1G	APTGT75A170D1G	
		100	2.0	SP4	YES	APTGT100DA170TG	APTGT100SK170TG	APTGT100A170TG	
		150	2.0	SP6	option	APTGT150DA170G	APTGT150SK170G	APTGT150A170G	
		200	2.0	D3	option	APTGT200DA170D3G	APTGT200SK170D3G	APTGT200A170D3G	
		225	2.0	SP6	option	APTGT225DA170G	APTGT225SK170G	APTGT225A170G	
		300	2.0	SP6	option	APTGT300DA170G	APTGT300SK170G	APTGT300A170G	
		300	2.0	D3	option	APTGT300DA170D3G	APTGT300SK170D3G	APTGT300A170D3G	



3 PHASE BRIDGE

V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	NPT FAST	30	2.1	SP3	YES	APTGF30X60T3G
		50	2.1	SP3	YES	APTGF50X60T3G
	TRENCH 3	30	1.5	SP3	YES	APTGT30X60T3G
		50	1.5	SP3	YES	APTGT50X60T3G
		75	1.5	SP3	YES	APTGT75X60T3G
1200	NPT FAST	15	3.2	SP3	YES	APTGF15X120T3G
		25	3.2	SP3	YES	APTGF25X120T3G
	TRENCH 3	25	1.7	SP3	YES	APTGT25X120T3G
		35	1.7	SP3	YES	APTGT35X120T3G
	TRENCH 4	40	1.85	SP3	YES	APTGL40X120T3G



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SP1



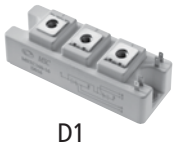
SP3



SP4



SP6



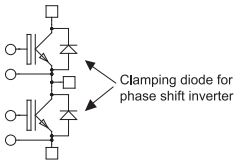
D1



D3

All Power Modules RoHS Compliant

IGBT Power Modules

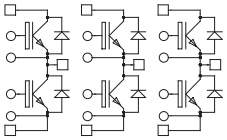


PHASE LEG FOR WELDING APPLICATION

V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
1200	NPT FAST	100	3.2	SP3	YES	APTGF100A120T3WG
		150	3.2	SP3	YES	APTGF150A120T3WG



SP3

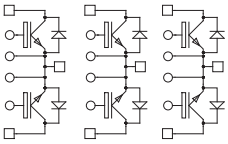


TRIPLE PHASE LEG

V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	NPT FAST	90	2.1	SP6-P	option	APTGF90TA60PG
	TRENCH 3	50	1.5	SP6-P	option	APTGT50TA60PG
		75	1.5	SP6-P	option	APTGT75TA60PG
		150	1.5	SP6-P	option	APTGT150TA60PG
1200	NPT FAST	50	3.2	SP6-P	option	APTGF50TA120PG
	TRENCH 3	75	1.7	SP6-P	option	APTGT75TA120PG
		100	1.7	SP6-P	YES	APTGT100TA120TPG
	TRENCH 4	120	1.85	SP6-P	YES	APTGL120TA120TPG



SP4

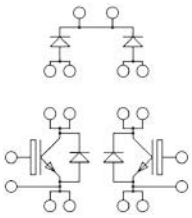


TRIPLE DUAL COMMON SOURCE

V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	TRENCH 3	50	1.5	SP6-P	option	APTGT50TDU60PG
		75	1.5	SP6-P	option	APTGT75TDU60PG
		100	1.5	SP6-P	option	APTGT100TDU60PG
		150	1.5	SP6-P	option	APTGT150TDU60PG
1200	NPT FAST	50	3.2	SP6-P	option	APTGF50TDU120PG
	TRENCH 3	75	1.7	SP6-P	option	APTGT75TDU120PG
	TRENCH 4	120	1.85	SP6-P	YES	APTGL120TDU120TPG
1700	TRENCH 3	50	2.0	SP6-P	option	APTGT50TDU170PG



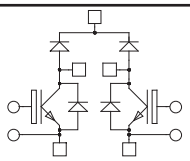
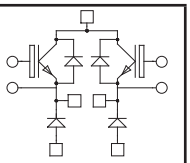
SP6-P



INTERLEAVED PFC

V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	NPT FAST	50	2.1	SP3	YES	APTGF50VDA60T3G
1200		50	3.2	SP3	YES	APTGF50VDA120T3G

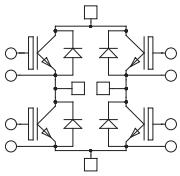
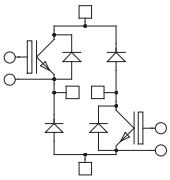
DUAL CHOPPER

V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	 ...DDA...	 ...DSK...
600	NPT FAST	50	2.1	SP3	YES	APTGF50DDA60T3G	APTGF50DSK60T3G
	TRENCH 3	50	1.5	SP3	YES	APTGT50DDA60T3G	APTGT50DSK60T3G
		75	1.5	SP3	YES	APTGT75DDA60T3G	APTGT75DSK60T3G
1200	NPT FAST	25	3.2	SP3	YES	APTGF25DDA120T3G	APTGF25DSK120T3G
		50	3.2	SP3	YES	APTGF50DDA120T3G	APTGF50DSK120T3G
		75	3.2	SP4	YES	APTGF75DDA120TG	APTGF75DSK120TG
	TRENCH 3	50	1.7	SP3	YES	APTGT50DDA120T3G	APTGT50DSK120T3G
	TRENCH 4	60	1.85	SP3	YES	APTGL60DDA120T3G	APTGL60DSK120T3G
		90	1.85	SP3	YES	APTGL90DDA120T3G	APTGL90DSK120T3G

All Power Modules RoHS Compliant

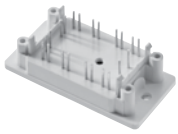
IGBT Power Modules

FULL & ASYMMETRICAL BRIDGE

V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	 ...H...	 ...DH...	
600	NPT FAST	30	2.1	SP1	YES	APTGF30H60T1G	N/A	
		30	2.1	SP3	YES	APTGF30H60T3G	N/A	
		50	2.1	SP1	YES	APTGF50H60T1G	APTGF50DH60T1G	
		50	2.1	SP2	YES	APTGF50H60T2G	N/A	
		50	2.1	SP3	YES	APTGF50H60T3G	N/A	
		90	2.1	SP3	YES	APTGF90H60T3G	APTGF90DH60T3G	
		180	2.1	SP6	-	APTGF180H60G	APTGF180DH60G	
	TRENCH 3	20	1.5	SP1	YES	APTGT20H60T1G	N/A	
		30	1.5	SP1	YES	APTGT30H60T1G	N/A	
		50	1.5	SP1	YES	APTGT50H60T1G	APTGT50DH60T1G	
		50	1.5	SP2	YES	APTGT50H60T2G	N/A	
		50	1.5	SP3	YES	APTGT50H60T3G	N/A	
		75	1.5	SP1	YES	APTGT75H60T1G	APTGT75DH60T1G	
		75	1.5	SP2	YES	APTGT75H60T2G	N/A	
		75	1.5	SP3	YES	APTGT75H60T3G	N/A	
		100	1.5	SP4	YES	APTGT100H60TG	APTGT100DH60TG	
		100	1.5	SP3	YES	APTGT100H60T3G	APTGT100DH60T3G	
		150	1.5	SP4	YES	APTGT150H60TG	APTGT150DH60TG	
		200	1.5	SP6	-	APTGT200H60G	APTGT200DH60G	
		300	1.5	SP6	-	APTGT300H60G	APTGT300DH60G	
650	TRENCH 4 FAST	75	1.85	SP1	YES	APTGLQ75H65T1G	N/A	***NEW!***
		300	1.85	SP6	option	APTGLQ300H65G	N/A	***NEW!***
1200	NPT ULTRA FAST	25	2.1	SP2	YES	APTGFQ25H120T2G	N/A	
	NPT FAST	15	3.2	SP1	YES	APTGF15H120T1G	N/A	
		25	3.2	SP1	YES	APTGF25H120T1G	N/A	
		25	2.1	SP2	YES	APTGF25H120T2G	N/A	
		25	3.2	SP3	YES	APTGF25H120T3G	N/A	
		50	3.2	SP3	YES	N/A	APTGF50DH120T3G	
		50	3.2	SP4	YES	APTGF50H120TG	APTGF50DH120TG	
		75	3.2	SP4	YES	APTGF75H120TG	APTGF75DH120TG	
		150	3.2	SP6	-	APTGF150H120G	APTGF150DH120G	
	TRENCH 3	35	1.7	SP3	YES	APTGT35H120T3G	N/A	
		50	1.7	SP3	YES	N/A	APTGT50DH120T3G	
		50	1.7	SP4	YES	APTGT50H120TG	APTGT50DH120TG	
		50	1.7	SP3	YES	APTGT50H120T3G	N/A	
		75	1.7	SP3	YES	N/A	APTGT75DH120T3G	
		75	1.7	SP4	YES	APTGT75H120TG	APTGT75DH120TG	
		100	1.7	SP4	YES	N/A	APTGT100DH120TG	
		100	1.7	SP6	-	APTGT100H120G	N/A	
		150	1.7	SP6	-	APTGT150H120G	APTGT150DH120G	
		200	1.7	SP6	-	APTGT200H120G	APTGT200DH120G	
	TRENCH 4	40	1.85	SP1	YES	APTGL40H120T1G	N/A	
		60	1.85	SP3	YES	APTGL60H120T3G	APTGL60DH120T3G	
		90	1.85	SP3	YES	APTGL90H120T3G	APTGL90DH120T3G	
	TRENCH 4 FAST	40	2.05	SP1	YES	APTGLQ40H120T1G	N/A	***NEW!***
		75	2.05	SP3	YES	APTGLQ75H120T3G	N/A	***NEW!***
		200	2.05	SP6	option	APTGLQ200H120G	N/A	***NEW!***
1700	TRENCH 3	30	2.0	SP3	YES	APTGT30H170T3G	N/A	
		50	2.0	SP4	YES	APTGT50H170TG	APTGT50DH170TG	
		100	2.0	SP6	-	APTGT100H170G	APTGT100DH170G	
		150	2.0	SP6	-	APTGT150H170G	APTGT150DH170G	



SP1



SP2



SP3



SP4

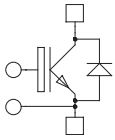


SP6 Full Bridge

All Power Modules RoHS Compliant

IGBT Power Modules

SINGLE SWITCH

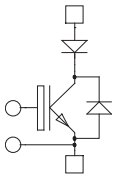


V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	NPT FAST	360	2.1	D4	-	APTGF360U60D4G
		500	2.1	D4	-	APTGF500U60D4G
		660	2.1	D4	-	APTGF660U60D4G
	TRENCH 3	750	1.5	D4	-	APTGT750U60D4G
1200	NPT FAST	530	3.2	D4	-	APTGF530U120D4G
	TRENCH 3	400	1.7	D4	-	APTGT400U120D4G
		600	1.7	D4	-	APTGT600U120D4G
	TRENCH 4	475	1.85	D4	-	APTGL475U120D4G
		700	1.85	D4	-	APTGL700U120D4G
1700	TRENCH 3	400	2.0	D4	-	APTGT400U170D4G
		600	2.0	D4	-	APTGT600U170D4G



D4

SINGLE SWITCH + SERIES DIODE

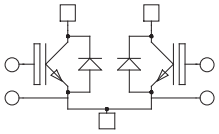


V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
1200	NPT FAST	200	3.2	SP6	-	APTGF200U120DG
		300	3.2	SP6	-	APTGF300U120DG
	TRENCH 4	475	1.85	SP6	-	APTGL475U120DAG



SP4

DUAL COMMON SOURCE



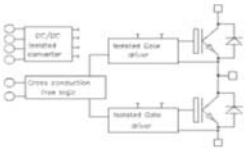
V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	NPT FAST	90	2.1	SP4	YES	APTGF90DU60TG
		180	2.1	SP4	YES	APTGF180DU60TG
		350	2.1	SP6	-	APTGF350DU60G
	TRENCH 3	100	1.5	SP4	YES	APTGT100DU60TG
		200	1.5	SP4	YES	APTGT200DU60TG
		300	1.4	SP6	-	APTGT300DU60G
		600	1.4	SP6	-	APTGT600DU60G
1200	NPT FAST	100	3.2	SP4	YES	APTGF100DU120TG
		150	3.2	SP4	YES	APTGF150DU120TG
		300	3.2	SP6	-	APTGF300DU120G
	TRENCH 3	50	1.7	SP4	YES	APTGT50DU120TG
		75	1.7	SP4	YES	APTGT75DU120TG
		100	1.7	SP4	YES	APTGT100DU120TG
		150	1.7	SP6	-	APTGT150DU120G
		150	1.7	SP4	YES	APTGT150DU120TG
		200	1.7	SP6	-	APTGT200DU120G
		300	1.7	SP6	-	APTGT300DU120G
		400	1.7	SP6	-	APTGT400DU120G
1700	TRENCH 3	100	2.0	SP4	YES	APTGT100DU170TG
		225	2.0	SP6	-	APTGT225DU170G
		300	2.0	SP6	-	APTGT300DU170G



SP6

Intelligent Power Modules

PHASE LEG



V_{CES} (V)	IGBT Type	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	NPT FAST	350	2.1	LP8	-	APTLGF350A608G
	TRENCH 3	400	1.5	LP8	-	APTLGT400A608G
1200	NPT FAST	300	3.2	LP8	-	APTLGF300A1208G
	TRENCH 3	300	1.7	LP8	-	APTLGT300A1208G
	TRENCH 4	325	1.8	LP8	-	APTLGL325A1208G



LP8

MOSFET Power Modules

CHOPPER

V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	DA...or...U2	SK...or...U3
100	MOS 5	11	100	SOT-227	-	APT10M11JVRU2	APT10M11JVRU3
		4.5	207	SP4	YES	APTM10DAM05TG	APTM10SKM05TG
		2.25	370	SP6	-	APTM10DAM02G	APTM10SKM02G
200	MOS 5	22	71	SOT-227	-	APT20M22JVRU2	APT20M22JVRU3
	MOS 7	8	147	SP4	YES	APTM20DAM08TG	APTM20SKM08TG
		5	250	SP6	option	APTM20DAM05G	APTM20SKM05G
		4	300	SP6	option	APTM20DAM04G	APTM20SKM04G
500	MOS 5	100	30	SOT-227	-	APT5010JVRU2	APT5010JVRU3
	MOS 7	100	30	SOT-227	-	APT5010JLLU2	APT5010JLLU3
		75	32	SOT-227	-	APT50M75JLLU2	APT50M75JLLU3
		19	125	SP6	option	APTM50DAM19G	APTM50SKM19G
		17	140	SP6	option	APTM50DAM17G	APTM50SKM17G
	MOS 8	65	43	SOT-227	-	APT58M50JU2	APT58M50JU3
600	COOLMOS	70	40	SOT-227	-	APT40N60JCU2	APT40N60JCU3
		24	70	SP1	YES	APTC60DAM24T1G	APTC60SKM24T1G
900	COOLMOS	120	25	SOT-227	-	APT33N90JCU2	APT33N90JCU3
		60	44	SP1	YES	APTC90DAM60T1G	APTC90SKM60T1G
1000	MOS 7	180	33	SP4	YES	APTM100DA18TG	APTM100SK18TG
		90	59	SP6	option	APTM100DAM90G	APTM100SKM90G
	MOS 8	330	17	SP1	YES	APTM100DA33T1G	APTM100SK33T1G
1200	MOS 8	560	13	SP1	YES	APTM120DA56T1G	APTM120SK56T1G
		300	23	SP1	YES	APTM120DA30T1G	N/A



SOT-227



SP1



SP3



SP4



SP6

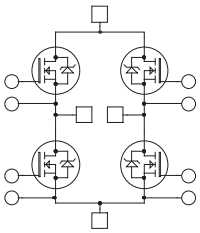
DUAL CHOPPER

V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	...DDA...	...DSK...
100	MOS 5	19	50	SP3	YES	APTM10DDAM19T3G	APTM10DSKM19T3G
		9	100	SP3	YES	APTM10DDAM09T3G	APTM10DSKM09T3G
500	MOS 7	100	24	SP3	YES	APTM50DDA10T3G	APTM50DSK10T3G
		65	37	SP3	YES	APTM50DDAM65T3G	APTM50DSKM65T3G
600	COOLMOS	45	38	SP1	YES	APTC60DDAM45T1G	APTC60DSKM45T1G
		70	29	SP1	YES	APTC60DDAM70T1G	APTC60DSKM70T1G
		35	54	SP3	YES	APTC60DDAM35T3G	APTC60DSKM35T3G
		24	70	SP3	YES	APTC60DDAM24T3G	APTC60DSKM24T3G
800	COOLMOS	150	21	SP3	YES	APTC80DDA15T3G	APTC80DSK15T3G
900	COOLMOS	120	23	SP1	YES	APTC90DDA12T1G	APTC90DSK12T1G
1000	MOS 7	350	17	SP3	YES	APTM100DDA35T3G	APTM100DSK35T3G
1200	MOS 7	570	13	SP3	YES	APTM120DDA57T3G	APTM120DSK57T3G

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All Power Modules RoHS Compliant

MOSFET Power Modules

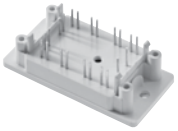


FULL BRIDGE

V_{DSS} (V)	MOSFET Type	$R_{DS(ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
100	FREDFET 5	4.5	207	SP6	-	APTM10HM05FG
		19	50	SP3	YES	APTM10HM19FT3G
		9	100	SP3	YES	APTM10HM09FT3G
200	FREDFET 7	20	62	SP4	YES	APTM20HM20FTG
		16	74	SP4	YES	APTM20HM16FTG
		10	125	SP6	-	APTM20HM10FG
		8	147	SP6	-	APTM20HM08FG
500	FREDFET 7	140	18	SP3	YES	APTM50H14FT3G
		100	24	SP3	YES	APTM50H10FT3G
		75	32	SP4	YES	APTM50HM75FTG
		75	32	SP3	YES	APTM50HM75FT3G
		65	37	SP4	YES	APTM50HM65FTG
		65	37	SP3	YES	APTM50HM65FT3G
		38	64	SP6	-	APTM50HM38FG
		35	70	SP6	-	APTM50HM35FG
	FREDFET 8	150	19	SP1	YES	APTM50H15FT1G
600	COOLMOS	70	29	SP1	YES	APTC60HM70T1G
		45	38	SP1	YES	APTC60HM45T1G
		83	21	SP2	YES	APTC60HM83FT2G
		70	29	SP3	YES	APTC60HM70T3G
		35	54	SP3	YES	APTC60HM35T3G
		24	70	SP3	YES	APTC60HM24T3G
	FREDFET 8	230	15	SP1	YES	APTM60H23FT1G
800	COOLMOS	150	21	SP1	YES	APTC80H15T1G
		290	11	SP3	YES	APTC80H29T3G
		150	21	SP3	YES	APTC80H15T3G
900	COOLMOS	120	23	SP1	YES	APTC90H12T1G
		120	23	SP2	YES	APTC90H12T2G
		60	44	SP3	YES	APTC90HM60T3G
1000	FREDFET 7	450	14	SP3	YES	APTM100H45FT3G
		350	17	SP4	YES	APTM100H35FTG
		350	17	SP3	YES	APTM100H35FT3G
		180	33	SP6	-	APTM100H18FG
	FREDFET 8	460	14	SP3	YES	APTM100H46FT3G
1200	FREDFET 7	290	25	SP6	-	APTM120H29FG
	FREDFET 8	1400	6	SP1	YES	APTM120H140FT1G



SP1



SP2



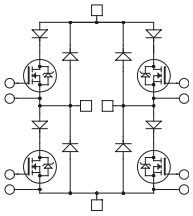
SP3



SP4

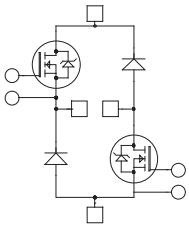


SP6



FULL BRIDGE + SERIES AND PARALLEL DIODES

V_{DSS} (V)	MOSFET Type	$R_{DS(ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
200	MOS 7	20	62	SP4	YES	APTM20HM20STG
500	MOS 7	75	32	SP4	YES	APTM50HM75STG
1000	MOS 7	450	13	SP4	YES	APTM100H45STG



ASYMMETRICAL BRIDGE

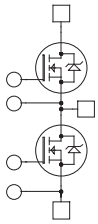
V_{DSS} (V)	MOSFET Type	$R_{DS(ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
100	MOS 5	9	100	SP3	YES	APTM10DHM09T3G
		4.5	207	SP6	-	APTM10DHM05G
200	MOS 7	16	77	SP3	YES	APTM20DHM16T3G
		8	147	SP6	-	APTM20DHM08G
500	MOS 7	38	64	SP6	-	APTM50DHM38G
		35	70	SP6	-	APTM50DHM35G
	MOS 8	65	32	SP3	YES	APTM50DHM65T3G
600	COOLMOS	24	70	SP3	YES	APTC60DHM24T3G

"CoolMOS™" is a trademark of Infineon Technologies AG".

All Power Modules RoHS Compliant

MOSFET Power Modules

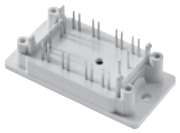
PHASE LEG



V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
100	FREDFET 5	4.5	207	SP4	YES	APTM10AM05FTG
		2.25	370	SP6	option	APTM10AM02FG
200	FREDFET 7	10	125	SP4	YES	APTM20AM10FTG
		8	147	SP4	YES	APTM20AM08FTG
		5	250	SP6	option	APTM20AM05FG
		4	300	SP6	option	APTM20AM04FG
500	FREDFET 7	38	64	SP4	YES	APTM50AM38FTG
		35	70	SP4	YES	APTM50AM35FTG
		19	125	SP6	option	APTM50AM19FG
		17	140	SP6	option	APTM50AM17FG
600	COOLMOS	45	38	SP1	YES	APTC60AM45T1G
		42	40	SP2	-	APTC60AM42F2G
		35	54	SP1	YES	APTC60AM35T1G
		24	70	SP1	YES	APTC60AM24T1G
		24	70	SP2	-	APTC60AM242G
	FREDFET 8	110	30	SP1	YES	APTM60A11FT1G
900	COOLMOS	60	44	SP1	YES	APTC90AM60T1G
		60	44	SP2	-	APTC90AM602G
1000	FREDFET 7	180	33	SP4	YES	APTM100A18FTG
		90	59	SP6	option	APTM100AM90FG
	FREDFET 8	400	16	SP1	YES	APTM100A40FT1G
1200	FREDFET 7	290	25	SP4	YES	APTM120A29FTG
		150	45	SP6	option	APTM120A15FG
	FREDFET 8	650	12	SP1	YES	APTM120A65FT1G



SP1



SP2



SP4

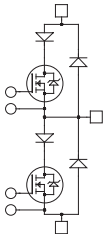


SP6



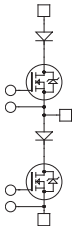
SP6-P

PHASE LEG + SERIES AND PARALLEL DIODES



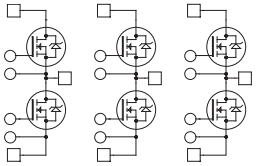
V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
200	MOS 7	10	125	SP4	YES	APTM20AM10STG
		6	225	SP6	-	APTM20AM06SG
500	MOS 7	38	64	SP4	YES	APTM50AM38STG
		24	110	SP6	-	APTM50AM24SG
1000	MOS 7	230	26	SP4	YES	APTM100A23STG
		130	49	SP6	-	APTM100A13SG
1200	MOS 7	200	37	SP6	-	APTM120A20SG

PHASE LEG + SERIES DIODES



V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
1000	MOS 7	130	49	SP6	-	APTM100A13DG
1200	MOS 7	200	37	SP6	-	APTM120A20DG

TRIPLE PHASE LEG



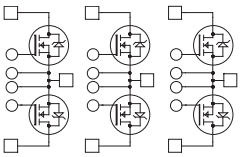
V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
75	MOSFET	4.2	90	SP6-P	option	APTM08TAM04PG
100	FREDFET 5	19	50	SP6-P	option	APTM10TAM19FPG
		9	100	SP6-P	option	APTM10TAM09FPG
200	FREDFET 7	16	74	SP6-P	option	APTM20TAM16FPG
500	FREDFET 7	65	37	SP6-P	option	APTM50TAM65FPG
600	COOLMOS	35	54	SP6-P	option	APTC60TAM35PG
		24	70	SP6-P	YES	APTC60TAM24TPG
800	COOLMOS	150	21	SP6-P	option	APTC80TA15PG
900	COOLMOS	60	44	SP6-P	YES	APTC90TAM60TPG
1000	FREDFET 7	350	17	SP6-P	option	APTM100TA35FPG

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All Power Modules RoHS Compliant

MOSFET Power Modules

TRIPLE DUAL COMMON SOURCE

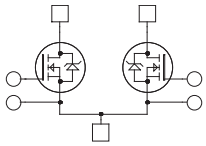


V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
100	MOS 5	9	100	SP6-P	option	APTM10TDUM09PG
600	COOLMOS	35	54	SP6-P	option	APTC60TDUM35PG
800	COOLMOS	150	21	SP6-P	option	APTC80TDU15PG
1200	MOS 7	570	13	SP6-P	option	APTM120TDU57PG



SP1

DUAL COMMON SOURCE



V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
100	MOS 5	2.25	370	SP6	-	APTM10DUM02G
200	MOS 7	8	147	SP4	YES	APTM20DUM08TG
		5	250	SP6	-	APTM20DUM05G
		4	300	SP6	-	APTM20DUM04G
500	MOS 7	35	70	SP4	YES	APTM50DUM35TG
		17	140	SP6	-	APTM50DUM17G
1000	MOS 7	90	59	SP6	-	APTM100DUM90G
1200	MOS 7	150	45	SP6	-	APTM120DU15G

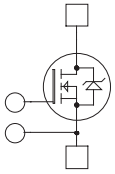


SP3



SP4

SINGLE SWITCH

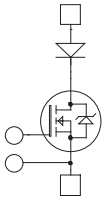


V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
100	FREDFET 5	2.25	430	SP6	option	APTM10UM02FAG
		1.5	640	SP6	option	APTM10UM01FAG
200	FREDFET 7	3	434	SP6	option	APTM20UM03FAG
500	FREDFET 7	9	371	SP6	option	APTM50UM09FAG
1000	FREDFET 7	60	97	SP6	option	APTM100UM60FAG
		45	160	SP6	option	APTM100UM45FAG
1200	FREDFET 7	70	126	SP6	option	APTM120UM70FAG



SP6

SINGLE SWITCH + SERIES DIODE

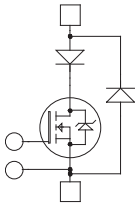


V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
1000	MOS 7	65	110	SP6	-	APTM100UM65DAG
		45	160	SP6	-	APTM100UM45DAG
1200	MOS 7	70	126	SP6	-	APTM120UM70DAG



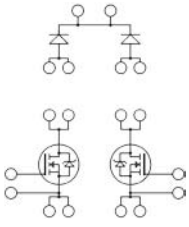
SP6-P

SINGLE SWITCH + SERIES AND PARALLEL DIODES



V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
200	MOS 7	4	310	SP6	option	APTM20UM04SAG
500	MOS 7	13	250	SP6	option	APTM50UM13SAG
1000	MOS 7	65	110	SP6	option	APTM100UM65SAG
1200	MOS 7	100	86	SP6	option	APTM120U10SAG

INTERLEAVED PFC



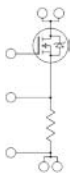
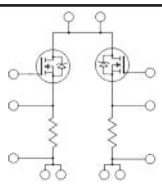
V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
600	COOLMOS	45	38	SP1	YES	APTC60VDAM45T1G
		24	70	SP3	YES	APTC60VDAM24T3G
1000	MOS 7	350	17	SP3	YES	APTM100VDA35T3G
1200		570	13	SP3	YES	APTM120VDA57T3G

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All Power Modules RoHS Compliant

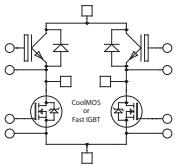
MOSFET Power Modules

SINGLE AND DUAL LINEAR MOSFET

V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	Shunt Resistor (mR)	Package	NTC		
100	MOS 5	9	4.4	SP1 or SP3	YES	APTML10UM09R004T1AG	APTML102UM09R004T3AG
200		18	10		YES	APTML20UM18R010T1AG	APTML202UM18R010T3AG
500	MOSFET Linear	90	20		YES	APTML50UM90R020T1AG	APTML502UM90R020T3AG
600		125	20		YES	APTML60U12R020T1AG	APTML602U12R020T3AG
1000	MOS 4 Linear	600	20		YES	APTML100U60R020T1AG	APTML1002U60R020T3AG

Renewable Energy Power Modules

FULL BRIDGE

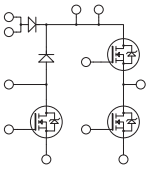


V_{CES} (V)	Technology	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	Mix Trench IGBT & NPT IGBT	50	2.1/1.5	SP3	YES	APTGV50H60T3G
		75	2.1/1.5	SP3	YES	APTGV75H60T3G
		100	2.1/1.5	SP3	YES	APTGV100H60T3G
	Mix Trench IGBT & CoolMOS	50	83mR/1.5	SP1	YES	APTCV40H60CT1G
		50	45mR/1.5	SP3	YES	APTCV50H60T3G
1200	Mix Trench IGBT & NPT IGBT	25	3.2/1.7	SP3	YES	APTGV25H120T3G
		50	3.2/1.7	SP3	YES	APTGV50H120T3G


SP1

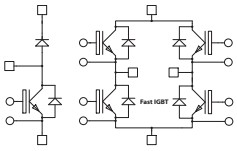

SP3

PFC + BYPASS DIODE + PHASE LEG



V_{CES} (V)	Technology	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Special	Part Number
600	COOLMOS	38	45mR	SP1	N/A	10A PFC SiC diode	APTC60AM45BC1G
		38	45mR	SP1	N/A	-	APTC60AM45B1G
		27	83mR	SP1	N/A	10A PFC SiC diode	APTC60AM83BC1G
		27	83mR	SP1	N/A	-	APTC60AM83B1G

PFC + FULL BRIDGE

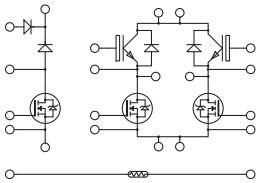


V_{CES} (V)	Technology	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	Mix Trench IGBT & NPT IGBT	50	2.1/1.5	SP4	-	APTGV50H60BG
		100	2.1/1.5	SP6-P	YES	APTGV100H60BTPG
1200	Mix Trench IGBT & NPT IGBT	25	3.2/1.7	SP4	-	APTGV25H120BG
		50	3.2/1.7	SP6-P	YES	APTGV50H120BTPG


SP3F


SP4

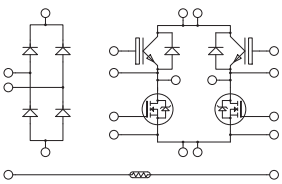
PFC + BYPASS DIODE + FULL BRIDGE



V_{CES} (V)	Technology	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Special	Part Number
600	Mix Trench IGBT & CoolMos	38	1.5/45mR	SP3F	YES	20A PFC SiC diode	APTCV60HM45BC20T3G
		38	1.5/45mR	SP3F	YES	-	APTCV60HM45BT3G
		29	1.5/70mR	SP3F	YES	-	APTCV60HM70BT3G
	COOLMOS	29	70mR	SP3F	YES	-	APTC60HM70BT3G
	Mix Trench IGBT & NPT IGBT	50	3.2/1.7	SP3F	YES	-	APTGV50H60BT3G


SP6-P

SECONDARY FAST RECTIFIER + FULL BRIDGE

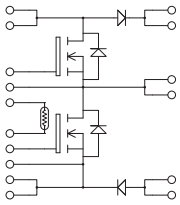


V_{CES} (V)	Technology	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Special	Part Number
600	Mix Trench IGBT & CoolMos	38	1.5/45mR	SP3F	YES	20A SiC antiparallel diode	APTCV60HM45RCT3G
		38	1.5/45mR	SP3F	YES	-	APTCV60HM45RT3G
		29	1.5/70mR	SP3F	YES	-	APTCV60HM70RT3G
	COOLMOS	29	70mR	SP3F	YES	-	APTC60HM70RT3G
	TRENCH 3	50	1.5	SP3F	YES	-	APTGT50H60RT3G

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Renewable Energy Power Modules

BOOST BUCK

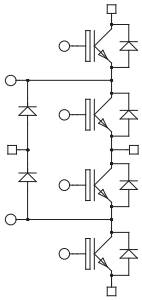


V_{CES} (V)	Technology	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	COOLMOS	70	24mR	SP3F	YES	APTC60BBM24T3G
600	TRENCH 3	100	1.5	SP3F	YES	APTGT100BB60T3G



SP1

3-LEVEL NPC INVERTER



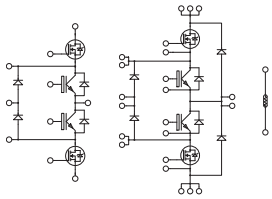
V_{CES} (V)	Technology	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number
600	TRENCH 3	20	1.5	SP1	-	APTGT20TL601G
		30	1.5	SP3	YES	APTGT30TL60T3G
		30	1.5	SP1	-	APTGT30TL601G
		50	1.5	SP3	YES	APTGT50TL60T3G
		50	1.5	SP1	-	APTGT50TL601G
		75	1.5	SP3	YES	APTGT75TL60T3G
		100	1.5	SP3	YES	APTGT100TL60T3G
		150	1.5	SP6	-	APTGT150TL60G
		200	1.5	SP6	-	APTGT200TL60G
		300	1.5	SP6	-	APTGT300TL60G
	NPT FAST	30	2.1	SP1	-	APTGF30TL601G
		50	2.1	SP3	YES	APTGF50TL60T3G
1200	TRENCH 4	60	1.85	SP3	YES	APTGL60TL120T3G
		240	1.8	SP6	-	APTGL240TL120G
1700	TRENCH 3	100	2.0	SP6	-	APTGT100TL170G



SP3



SP3F

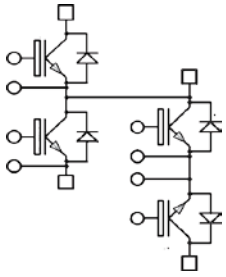


SP1 SP3

V_{CES} (V)	Technology	$R_{DS\ (ON)}$ Coolmos (mΩ)	$V_{CE\ (on)}$ IGBT (V) / I_C (A)	Package	NTC	Part Number
600	Mix Trench IGBT & CoolMOS	24	1.5/75	SP3	YES	APTCV60TLM24T3G
		45	1.5/75	SP3	YES	APTCV60TLM45T3G
		70	1.5/50	SP3	YES	APTCV60TLM70T3G
		99	1.5/30	SP3	YES	APTCV60TLM99T3G
900	Mix Trench IGBT & CoolMOS	120	1.85/50	SP3	YES	APTCV90TL12T3G



SP6 3-Level



T-TYPE 3-LEVEL INVERTER

V_{CES} (V)	Technology	I_C (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Special	Part Number	
600/1200	TRENCH 4 FAST	40	2.05	SP3F	YES	10A/600V SiC	APTGLQ40HR120CT3G	*NEW!*
		80	2.05	SP3F	YES	30A/600V SiC	APTGLQ80HR120CT3G	*NEW!*
		200	2.05	SP6	NO	-	APTGLQ200HR120G	*NEW!*

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Power Modules with SiC Schottky Diodes

Silicone Carbide (SiC) Schottky Diodes offer superior dynamic and thermal performance over conventional Silicon power diodes. The main advantages of the SiC Schottky Diodes are:

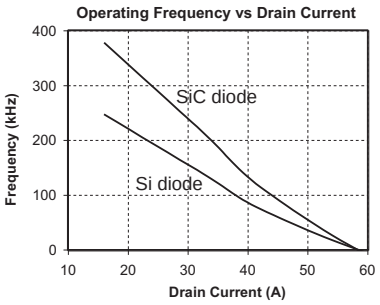
- Essentially zero forward and reverse recovery = reduced switch and diode switching losses
- Temperature independent switching behavior = stable high temperature performance
- Positive temperature coefficient of VF = ease of parallel operation
- Usable 175°C Junction Temperature = safely operate at higher temperatures

Extremely fast switching of SiC Schottky diode enables designs with:

- Improved System Efficiency
- Higher Reliability
- Lower System Switching Losses
- Lower System Cost
  - Smaller EMI Filter
  - Smaller Magnetic Components
  - Smaller Heat-Sink
  - Smaller Switches, Eliminate Snubbers
- Reduced System Size .
  - Fewer / Smaller Components

Applications:

- PFC
- Output Rectification
- Solar Inverter
- Motor Control
- Snubber Diode



Diode Power Modules with SiC Diodes

DUAL DIODE

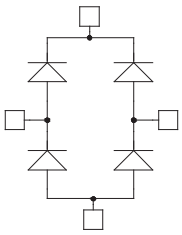
V_{RRM} (V)	DIODE Type	IF (A) T_C=100° C	VF (V) T_J=25° C	Package	Anti-Parallel	Parallel
600	SiC	20	1.6	SOT-227	APT2X20DC60J	APT2X21DC60J
		30	1.6	SOT-227	APT2X30DC60J	APT2X31DC60J
		40	1.6	SOT-227	APT2X40DC60J	APT2X41DC60J
		50	1.6	SOT-227	APT2X50DC60J	APT2X51DC60J
		60	1.6	SOT-227	APT2X60DC60J	APT2X61DC60J
		90	1.6	SP1	-	APTDC902U601G
1200	SiC	20	1.6	SOT-227	APT2X20DC120J	APT2X21DC120J
		30	1.6	SOT-227	APT2X30DC120J	APT2X31DC120J
		40	1.6	SOT-227	APT2X40DC120J	APT2X41DC120J
		50	1.6	SOT-227	APT2X50DC120J	APT2X51DC120J
		60	1.6	SOT-227	APT2X60DC120J	APT2X61DC120J


SOT-227


SP1


SP3F

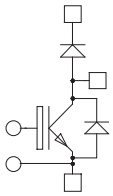
FULL BRIDGE



V_{RRM} (V)	DIODE Type	IF (A) T_C=100° C	VF (V) T_J=25° C	Package	Part Number
600	SiC	6	1.6	SOT-227	APT06DC60HJ
		10	1.6	SP1	APTDC10H601G
		20	1.6	SP1	APTDC20H601G
		40	1.6	SP1	APTDC40H601G
		40	1.6	SOT-227	APT40DC60HJ
1200	SiC	10	1.6	SOT-227	APT10DC120HJ
		20	1.6	SP1	APTDC20H1201G
		20	1.6	SOT-227	APT20DC120HJ
		40	1.6	SP1	APTDC40H1201G
		40	1.6	SOT-227	APT40DC120HJ

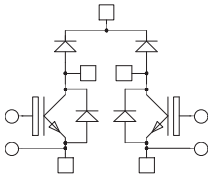
IGBT Power Modules with SiC Diodes

BOOST CHOPPER



V_{RRM} (V)	IGBT Type	IC (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number	
600	NPT	50	2.1	SOT-227	-	APT50GF60JCU2	
		90	2.1	SP1	YES	APTGF90DA60CT1G	
1200	NPT	15	3.2	SOT-227	-	APT15GF120JCU2	
		25	3.2	SOT-227	-	APT25GF120JCU2	
		50	3.2	SP1	YES	APTGF50DA120CT1G	
	TRENCH 4 FAST	25	2.05	SOT-227	-	APT25GLQ120JCU2	***NEW!***
		40	2.05	SOT-227	-	APT40GLQ120JCU2	***NEW!***

DUAL CHOPPER

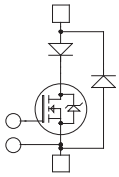


V_{RRM} (V)	IGBT Type	IC (A) T_C=80° C	$V_{CE\ (on)}$(V) at rated Ic	Package	NTC	Part Number	
1200	TRENCH 4 FAST	40	2.05	SP3F	YES	APTGLQ40DDA120CT3G	***NEW!***

All Power Modules RoHS Compliant

Power Modules with SiC Schottky Diodes

MOSFETs & COOLMOS™ Power Modules with SiC Diodes



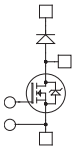
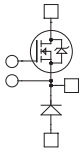
SINGLE SWITCH + SERIES FRED AND SIC PARALLEL DIODES

V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
1000	MOS7	65	110	SP6	option	APTM100UM65SCAVG
1200	MOS7	100	86	SP6	option	APTM120U10SCAVG



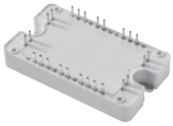
SOT-227

CHOPPER

V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	 …DA… or U2	 …SK… or U3
500	MOS8	65	43	SOT-227	-	APT58M50JCU2	APT58M50JCU3
600	COOLMOS	45	38	SOT-227	-	APT50N60JCCU2	N/A
		24	70	SP1	YES	APTC60DAM24CT1G	APTC60SKM24CT1G
		18	107	SP4	YES	APTC60DAM18CTG	N/A
900	COOLMOS	120	25	SOT-227	-	APT33N90JCCU2	APT33N90JCCU3
		60	44	SP1	YES	APTC90DAM60CT1G	APTC90SKM60CT1G
1000	MOS 8	330	20	SOT-227	-	APT26M100JCU2	APT26M100JCU3
		180	30	SP1	YES	APTM100DA18CT1G	N/A
1200	MOS 8	560	15	SOT-227	-	APT20M120JCU2	APT20M120JCU3
		300	23	SP1	YES	APTM120DA30CT1G	N/A

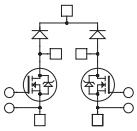
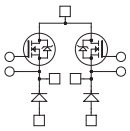


SP1



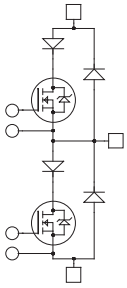
SP3F

DUAL CHOPPER

V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	 …DDA…	 …DSK…
600	COOLMOS	45	38	SP1	YES	APTC60DDAM45CT1G	APTC60DSKM45CT1G
		70	29	SP1	YES	APTC60DDAM70CT1G	APTC60DSKM70CT1G



SP4

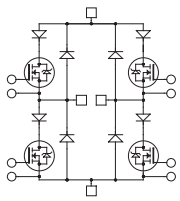


PHASE LEG + SERIES FRED AND SIC PARALLEL DIODES

V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
500	MOS 7	38	67	SP4	YES	APTM50AM38SCTG
		24	110	SP6	-	APTM50AM24SCG
600	COOLMOS	35	54	SP4	YES	APTC60AM35SCTG
		24	70	SP4	YES	APTC60AM24SCTG
		18	107	SP6	-	APTC60AM18SCG
900	COOLMOS	60	44	SP4	YES	APTC90AM60SCTG
800	COOLMOS	150	21	SP4	YES	APTC80A15SCTG
		100	32	SP4	YES	APTC80A10SCTG
		75	43	SP6	-	APTC80AM75SCG
1000	MOS 7	130	49	SP6	-	APTM100A13SCG



SP6

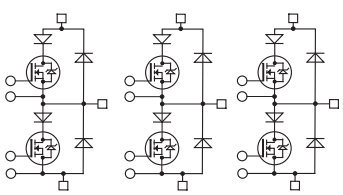


FULL BRIDGE + SERIES FRED AND SIC PARALLEL DIODES

V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number
500	MOS 7	75	34	SP4	YES	APTM50HM75SCTG
600	COOLMOS	70	29	SP4	YES	APTC60HM70SCTG
		45	38	SP4	YES	APTC60HM45SCTG
800	COOLMOS	290	11	SP4	YES	APTC80H29SCTG
900	COOLMOS	120	23	SP4	YES	APTC90H12SCTG
1000	MOS 7	450	14	SP4	YES	APTM100H45SCTG



SP6-P

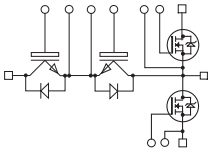


TRIPLE PHASE LEG

V_{DSS} (V)	MOSFET Type	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number	
600	COOLMOS	24	87	SP6-P	YES	APTC60TAM21SCTPAG	*NEW!*
1000	MOS 7	350	50	SP6-P	YES	APTM100TA35SCTPG	*NEW!*

"CoolMOS™" is a trademark of Infineon Technologies AG".

SiC MOSFET Power Modules

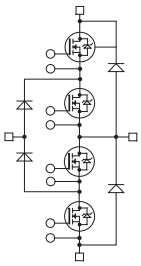


T-TYPE 3-LEVEL INVERTER

V_{CES} (V)	Technology	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number	
600/1200	IGBT & SiC MOSFET	110	20	SP3F	YES	APTMC120HR11CT3G	*NEW!*
		40	50	SP3F	YES	APTMC120HRM40CT3G	*NEW!*



SOT-227



3-LEVEL NPC INVERTER

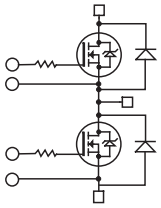
V_{CES} (V)	Technology	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number	
600	SiC MOSFET	110	20	SP3F	YES	APTMC60TL11CT3AG	*NEW!*
		55	40	SP3F	YES	APTMC60TLM55CT3AG	*NEW!*
		20	110	SP3F	YES	APTMC60TLM20CT3AG	*NEW!*
		14	160	SP6	-	APTMC60TLM14CAG	*NEW!*



SP1



SP3F

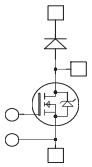


PHASE LEG

V_{CES} (V)	Technology	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number	
1200	SiC MOSFET	55	40	SP1	YES	APTMC120AM55CT1AG	*NEW!*
		20	100	SP1	YES	APTMC120AM20CT1AG	*NEW!*
		8	185	D3	-	APTMC120AM08CD3AG	*NEW!*



SP6 3-Level



BOOST CHOPPER

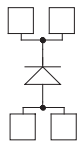
V_{CES} (V)	Technology	$R_{DS\ (ON)}$ (mΩ)	I_D (A) T_C=80° C	Package	NTC	Part Number	
1200	SiC MOSFET	40	50	SOT-227	-	APT50MC120JCU2	*NEW!*
		20	100		-	APT100MC120JCU2	*NEW!*



D3

DIODE Power Modules

SINGLE DIODE

V_{RRM} (V)	DIODE Type	IF (A) T_C=80° C	VF (V) T_J=25° C	Package	
200	FRED	500	1.1	LP4	APTDF500U20G
400		500	1.5		APTDF500U40G
600		450	1.8		APTDF450U60G
1000		430	2.3		APTDF430U100G
1200		400	2.5		APTDF400U120G



LP4

Non Isolated Packages

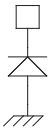


Half Pack



SDM

SINGLE DIODE - NON ISOLATED PACKAGE

V_{RRM} (V)	DIODE Type	IF (A) per Diode	VF (V) T_J=25° C	Package	 Cathode to Base	 Cathode to Base
600	FRED	100	1.35	Half-Pack	HU10260	HU10260R
		200			HU20260	HU20260R
400	RECTIFIER	300	1.1	SDM	SDM30004	SDM30004R
30	SCHOTTKY	180	0.55	Half-Pack	HS18230	HS18230R
		240			HS24230	HS24230R
35		180	0.70		HS18135	HS18135R
40		180	0.71		HS18140	HS18140R
		240	0.56		HS24040	HS24040R
45		120	0.55		HS12045	HS12045R
		180	0.72		HS18145	HS18145R
		240	0.57		HS24045	HS24045R
100		120	0.91		HS123100	HS123100R
		180			HS183100	HS183100R
		240	0.86		HS243100	HS243100R
150		240	0.87		HS246150	HS246150R
180		240	0.88		HS247180	HS247180R
200		240	0.89		HS247200	HS247200R



SM1

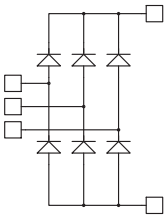


SM2



SM2-1

3-PHASE BRIDGE



V_{RRM} (V)	DIODE Type	IF (A) T_C=80° C	VF (V) T_J=25° C	Package	Part Number
1600	RECTIFIER	40	1.3	SP1	APTDR40X1601G
		90	1.3	SP1	APTDR90X1601G
800 1200 1600 1800	RECTIFIER	30	1.6	SM1	MSD30-08/12/16/18
		50	1.5	SM1	MSD50-08/12/16/18
		50	1.45	SM2-1	MSDM50-08/12/16/18
		52	1.8	SM2	MSD52-08/12/16/18
		75	1.6	SM2	MSD75-08/12/16/18
		75	1.38	SM2-1	MSDM75-08/12/16/18
		100	1.9	SM3	MSD100-08/12/16/18
		100	1.7	SM2-1	MSDM100-08/12/16/18
		130	1.8	SM3	MSD130-08/12/16/18
		150	1.28	SM3-1	MSDM150-08/12/16/18
		160	1.65	SM3	MSD160-08/12/16/18
		200	1.55	SM3	MSD200-08/12/16/18
		200	1.31	SM3-1	MSDM200-08/12/16/18

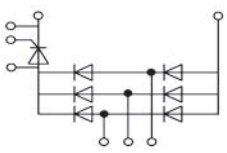


SM3



SM3-1

3-PHASE BRIDGE + THYRISTOR



V_{RRM} (V)	DIODE Type	IF (A) T_C=80° C	VF (V) T_J=25° C	Package	Part Number
1600	RECTIFIER THYRISTOR	75	1.4	SM4	MSDT75-16
		100	1.35	SM4	MSDT100-16
		150	1.35	SM4	MSDT150-16
		200	1.35	SM5	MSDT200-16



SM4

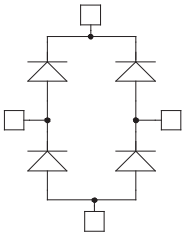


SM5

All Power Modules RoHS Compliant

DIODE Power Modules

FULL BRIDGE



V_{RRM} (V)	DIODE Type	IF (A) T_C=80° C	VF (V) T_J=25° C	Package Style	Part Number
200	FRED	30	1.0	SOT-227	APT30DF20HJ
		60	1.0	SOT-227	APT60DF20HJ
		100	1.0	SP4	APTDF100H20G
		200	1.0	SP6	APTDF200H20G
600		30	1.6	SOT-227	APT30DL60HJ
		30	1.8	SP1	APTDF30H601G
		30	1.8	SOT-227	APT30DF60HJ
		50	1.6	SOT-227	APT50DL60HJ
		60	1.8	SOT-227	APT60DF60HJ
		60	1.8	SP1	APTDF60H601G
		75	1.6	SOT-227	APT75DL60HJ
		100	1.6	SOT-227	APT100DL60HJ
		100	1.6	SP1	APTDF100H601G
		200	1.6	SP6	APTDF200H60G
1000		30	2.1	SOT-227	APT30DF100HJ
		60	2.1	SOT-227	APT60DF100HJ
		100	2.1	SP4	APTDF100H100G
		200	2.1	SP6	APTDF200H100G
1200		30	2.6	SP1	APTDF30H1201G
		30	2.6	SOT-227	APT30DF120HJ
		35	1.6	SOT-227	APT35DL120HJ
		50	1.6	SOT-227	APT50DL120HJ
		60	2.6	SP1	APTDF60H1201G
		60	2.6	SOT-227	APT60DF120HJ
		75	1.6	SOT-227	APT75DL120HJ
		100	2.5	SP1	APTDF100H1201G
		200	2.4	SP6	APTDF200H120G
1700		50	1.8	SOT-227	APT50DF170HJ
		75	1.8	SOT-227	APT75DF170HJ
		100	2.2	SP4	APTDF100H170G
		200	2.2	SP6	APTDF200H170G
45	SCHOTTKY	40	0.9	SOT-227	APT40DS04HJ
		60			APT60DS04HJ
100		40			APT40DS10HJ
		60			APT60DS10HJ
200		30			APT30DS20HJ
		60			APT60DS20HJ
200	RECTIFIER	10	1.3	VJ	VJ248M
400					VJ448M
1600		40		SOT-227	APT40DR160HJ
		90			APT90DR160HJ
250-700	Controlled Avalanche Rectifiers	10	1.3	VJ	VJ247M
450-900					VJ447M
660-1100					VJ647M



SOT-227



SP1



SP4



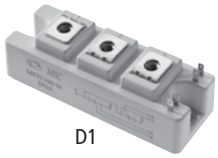
SP6



VJ

THYRISTOR & DIODE DOUBLER

V_{RRM} (V)	DIODE Type	IF (A) per Diode	VF/VTM (V) T_J=25° C	Package Style	Thyristor Diode Doubler	Thyristor Doubler
800 1200 1600	RECTIFIER THYRISTOR	25	1.8	SF1	MSFC25-08/12/16	MSTC25-08/12/16
		40	1.95		MSFC40-08/12/16	MSTC40-08/12/16
		60	1.65		MSFC60-08/12/16	MSTC60-08/12/16
		90	1.65		MSFC90-08/12/16	MSTC90-08/12/16
		110	1.65		MSFC110-08/12/16	MSTC110-08/12/16
		130	1.8	D1	MSFC130-08/12/16	MSTC130-08/12/16
		160	1.7		MSFC160-08/12/16	MSTC160-08/12/16



D1



SF1

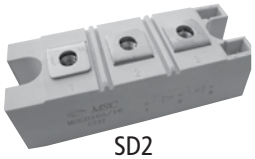
DIODE Power Modules

COMMON CATHODE - COMMON ANODE - DOUBLER

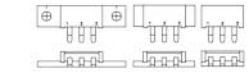
V_{RRM} (V)	DIODE Type	IF (A) per Diode	VF (V) T_J=25° C	Package	Common Cathode	Common Anode	Doubler
200	FRED	400	1.0	SP6	APTDF400KK20G	APTDF400AA20G	APTDF400AK20G
600			1.6		APTDF400KK60G	APTDF400AA60G	APTDF400AK60G
1000			2.1		APTDF400KK100G	APTDF400AA100G	APTDF400AK100G
1200			2.4		APTDF400KK120G	APTDF400AA120G	APTDF400AK120G
1700			2.2		APTDF400KK170G	APTDF400AA170G	APTDF400AK170G
800-1200-1600-1800	RECTIFIER	36	1.15	SD1	MSKD36-08/12/16/18	MSAD36-08/12/16/18	MSCD36-08/12/16/18
		60			MSKD60-08/12/16/18	MSAD60-08/12/16/18	MSCD60-08/12/16/18
		70			MSKD70-08/12/16/18	MSAD70-08/12/16/18	MSCD70-08/12/16/18
		100			MSKD100-08/12/16/18	MSAD100-08/12/16/18	MSCD100-08/12/16/18
		120			MSKD120-08/12/16/18	MSAD120-08/12/16/18	MSCD120-08/12/16/18
		165		SD2	MSKD165-08/12/16/18	MSAD165-08/12/16/18	MSCD165-08/12/16/18
		200			MSKD200-08/12/16/18	MSAD200-08/12/16/18	MSCD200-08/12/16/18
200	FRED	35	0.95	Mini-Mod	UFT7020	UFT7020A	UFT7020D
		60	0.98	TwinTower	UFT12520	UFT12520A	UFT12520D
		70	0.98	TO-249 Flat Pack	UFT14020	UFT14020A	UFT14020D
		100	0.98	TwinTower	UFT20020	UFT20020A	UFT20020D
			1.25		UFT20120	UFT20120A	UFT20120D
		200	0.98		UFT40020	UFT40020A	UFT40020D
300		35	1.20	Mini-Mod	UFT7130	UFT7130A	UFT7130D
400		70	1.25	TO-249 Flat Pack	UFT14140	UFT14140A	UFT14140D
		100	1.25	TwinTower	UFT20140	UFT20140A	UFT20140D
500		35	1.20	Mini-Mod	UFT7150	UFT7150A	UFT7150D
600			1.35		UFT7260SMxC	UFT7260SMxA	UFT7260SMxD
		70	1.35	TO-249 Flat Pack	UFT14260	UFT14260A	UFT14260D
800		60	1.35	TwinTower	UFT12780	UFT12780A	UFT12780D
		70	1.35	TO-249 Flat Pack	UFT14280	UFT14280A	UFT14280D
30	SCHOTTKY	30	0.47	TO-249 Flat Pack	FST16230	FST16230A	FST16230D
35		250	0.55	TwinTower	CPT50235	CPT50235A	CPT50235D
		300	0.65		CPT60035	CPT60035A	CPT60035D
40		150	0.76		CPT30040	CPT30040A	CPT30040D
45		40	0.53	Mini-Mod	FST8145	FST8145A	FST8145D
		80	0.65	TO-249 Flat Pack	FST16145	FST16145A	FST16145D
		80	0.74		FST16045	FST16045A	FST16045D
		100	0.68	TwinTower	CPT20145	CPT20145A	CPT20145D
		150	0.62		CPT30145	CPT30145A	CPT30145D
		150	0.77		CPT30045	CPT30045A	CPT30045D
		200	0.57		CPT40145	CPT40145A	CPT40145D
		250	0.55		CPT50145	CPT50145A	CPT50145D
		300	0.55		CPT60145	CPT60145A	CPT60145D
			0.65		CPT60045	CPT60045A	CPT60045D
50		60	0.8		CPT12050	CPT12050A	CPT12050D
		80	0.74	TO-249 Flat Pack	FST16050	FST16050A	FST16050D
60		150	0.78	TwinTower	CPT30050	CPT30050A	CPT30050D
			0.82		CPT30060	CPT30060A	CPT30060D
		250	0.73		CPT50060	CPT50060A	CPT50060D
80		200	0.89		CPT40080	CPT40080A	CPT40080D
90		80	0.96	TO-249 Flat Pack	FST16090	FST16090A	FST16090D
		150	0.98	TwinTower	CPT30090	CPT30090A	CPT30090D
		200	0.90		CPT40090	CPT40090A	CPT40090D
100		40	0.82	Mini-Mod	FST80100	FST80100A	FST80100D
		60	0.86	TO-249 9 Pins	FST60100	FST60100A	FST60100D
		75	0.94		FST153100	FST153100A	FST153100D
		80	0.96	TO-249 Flat Pack	FST160100	FST160100A	FST160100D
		150	0.98	Twin Tower	CPT300100	CPT300100A	CPT300100D
		200	0.91		CPT400100	CPT400100A	CPT400100D
		250	0.90		CPT500100	CPT500100A	CPT500100D
		300	0.85		CPT600100	CPT600100A	CPT600100D
150			0.85		CPT600150	CPT600150A	CPT600150D


SP6


SD1


SD2

Non Isolated Packages



SM1	SM3	SM5
SM2	SM4	SM6

x option for Mini-Mod Surface Mount Package


Mini-Mod Surface Mount


Mini-Mod


TO-249 Flat Pack


Twin Tower Non Isolated

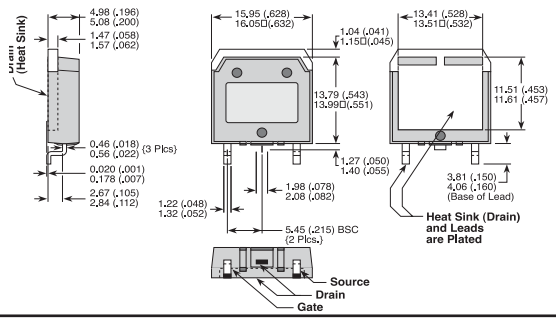

10-pin TO-249

All Power Modules RoHS Compliant

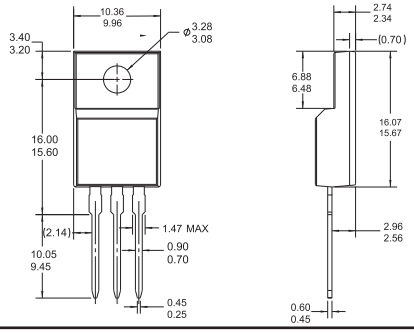
Package Outlines

Pin out location depends on the module configuration. Please refer to the product datasheet for pins assignment. All dimensions in millimeters.

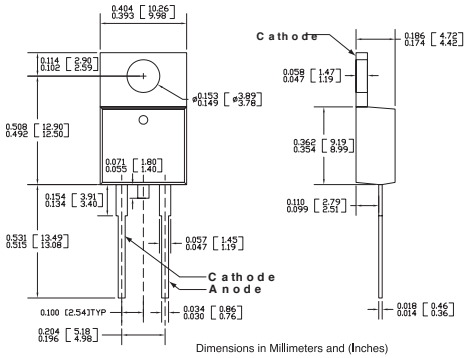
D³ Pak or TO-268



TO-220 [KF]

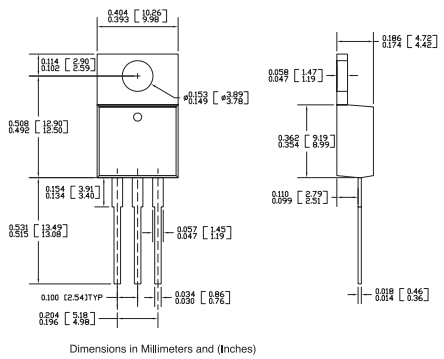


TO-220 2-Lead



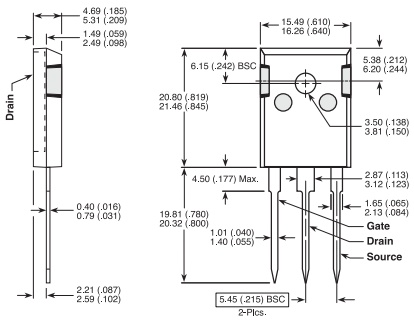
Dimensions in Millimeters and (Inches)

TO-220 3-Lead

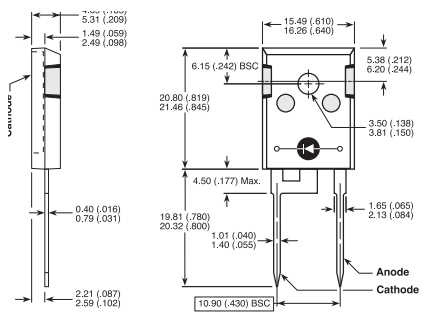


Dimensions in Millimeters and (Inches)

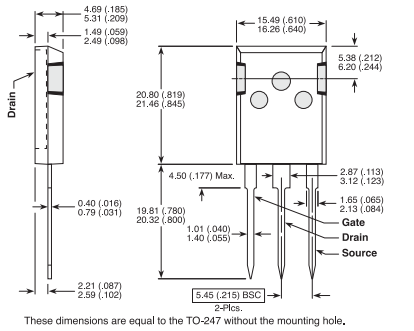
TO-247 3-Lead



TO-247 2-Lead

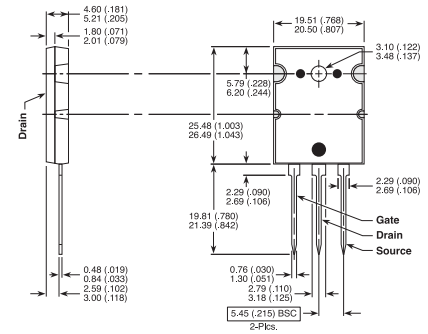


T-MAX®

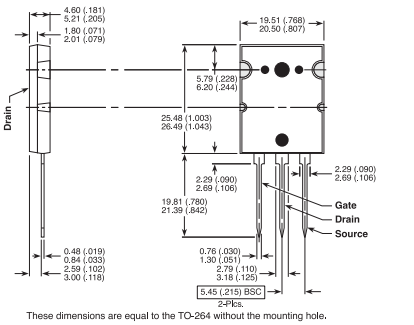


These dimensions are equal to the TO-247 without the mounting hole.

TO-264

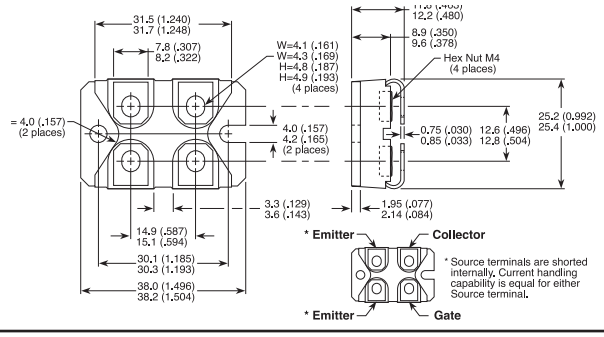


264 MAX™



These dimensions are equal to the TO-264 without the mounting hole.

ISOTOP® or SOT-227

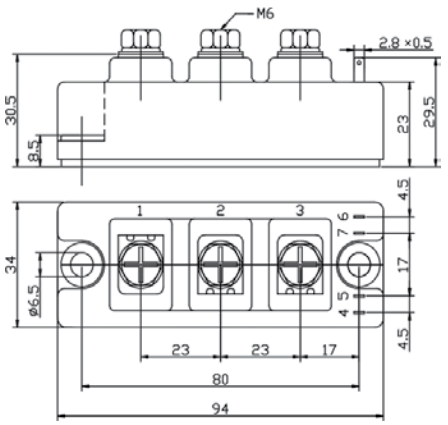


ISOTOP® is a registered trademark of SGS Thomson

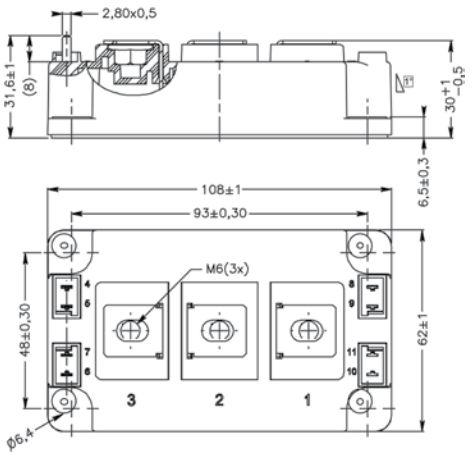
Power Module Outlines

Pin out location depends on the module configuration. Please refer to the product datasheet for pins assignment. All dimensions in millimeters.

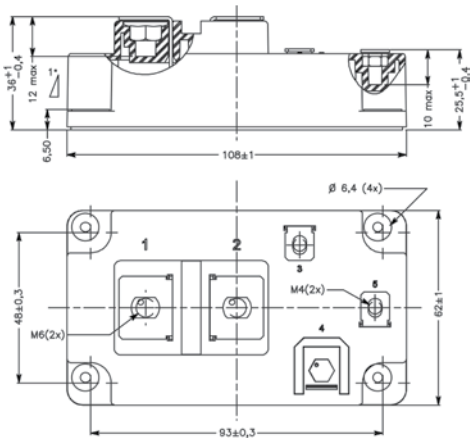
D1



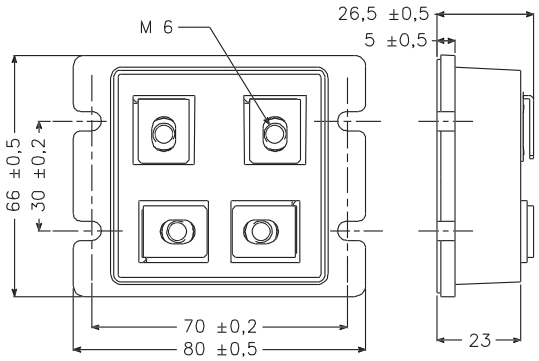
D3



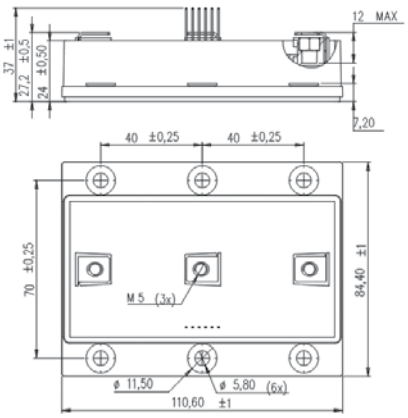
D4



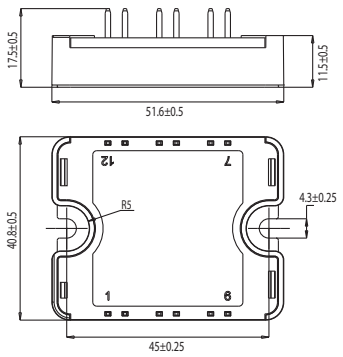
LP4



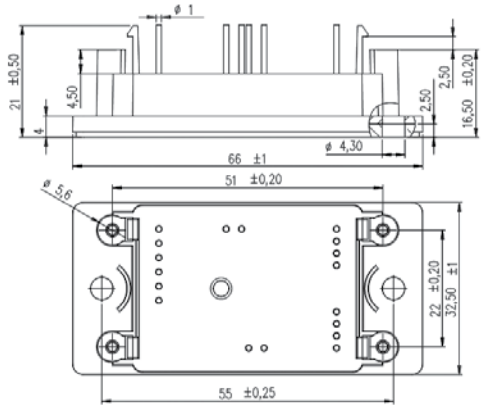
LP8



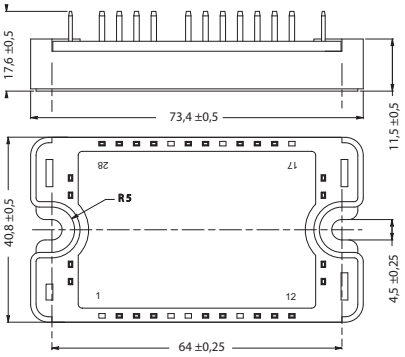
SP1



SP2



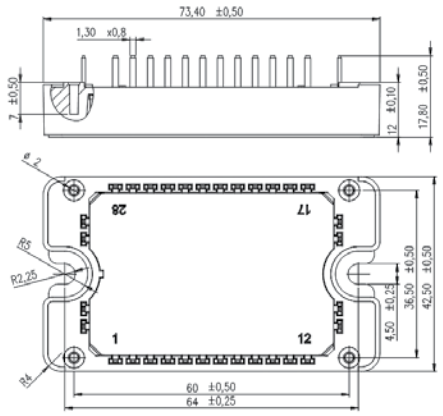
SP3



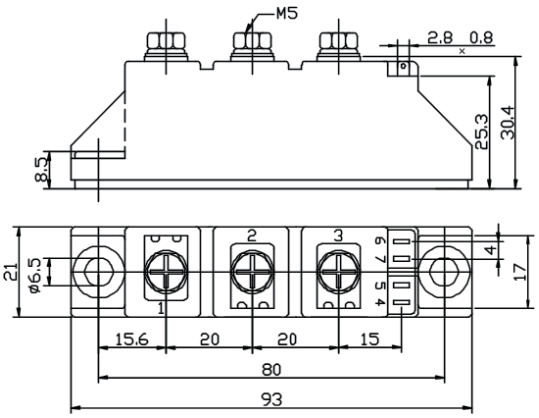
Power Module Outlines

Pin out location depends on the module configuration. Please refer to the product datasheet for pins assignment. All dimensions in millimeters.

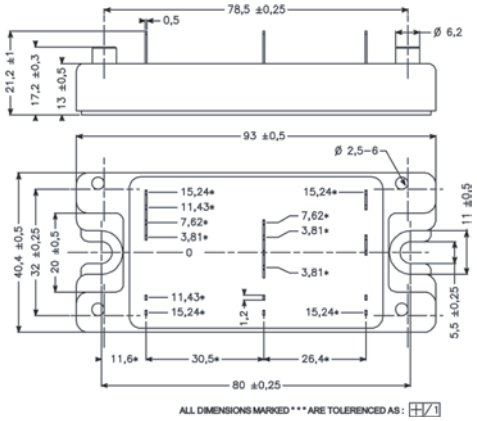
SP3F



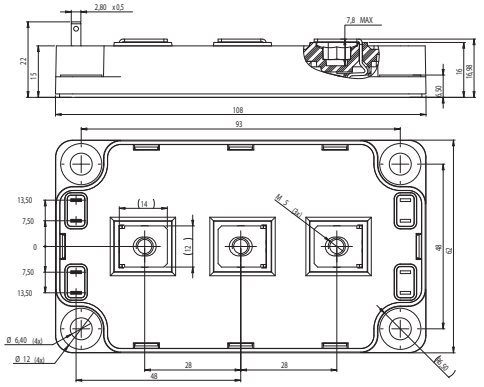
SF1



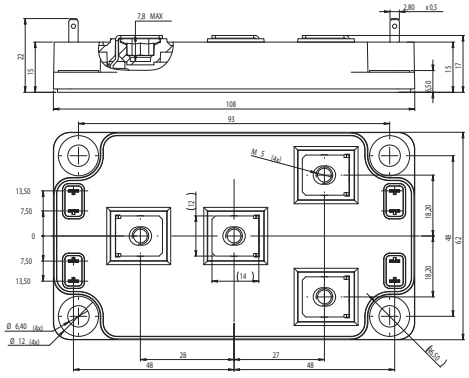
SP4



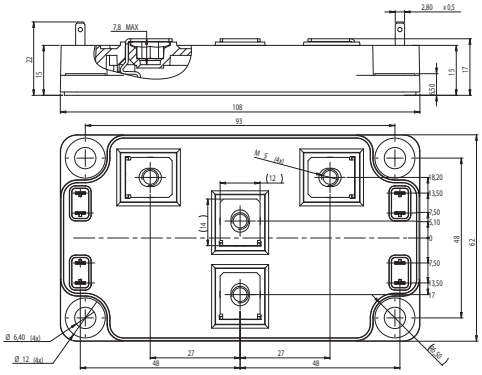
SP6 - 3 outputs



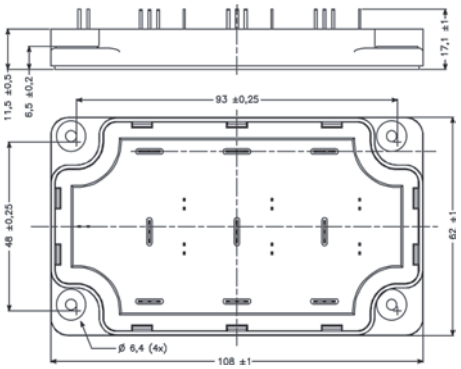
SP6 - 4 outputs



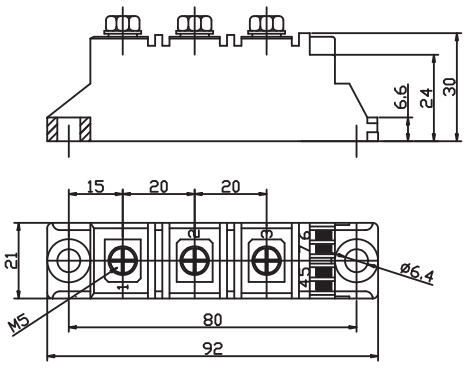
SP6 3-Level



SP6-P



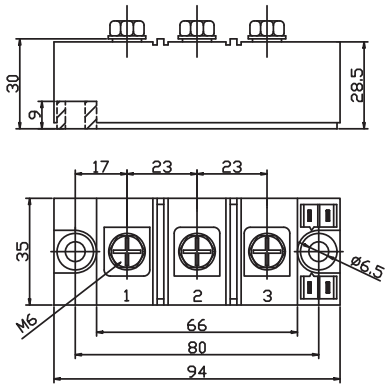
SD1



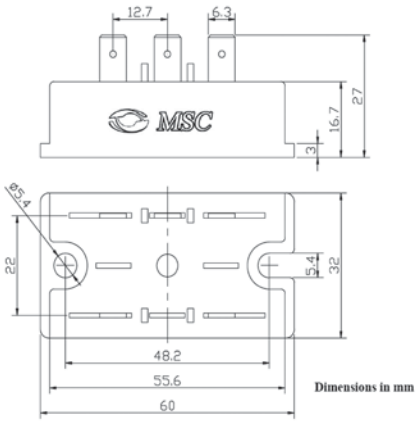
Power Module Outlines

Pin out location depends on the module configuration. Please refer to the product datasheet for pins assignment. All dimensions in millimeters.

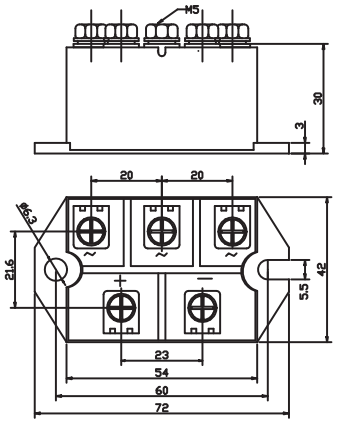
SD2



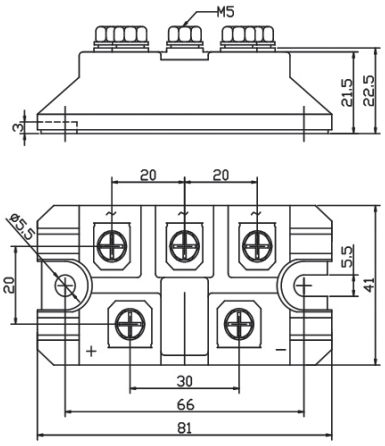
SM1



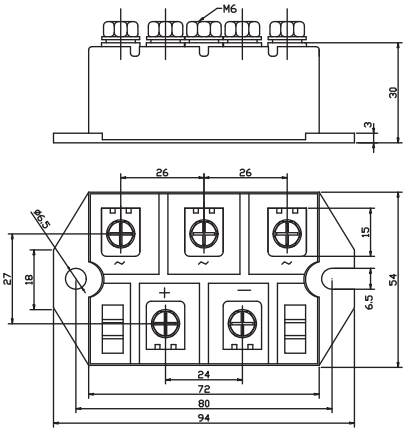
SM2



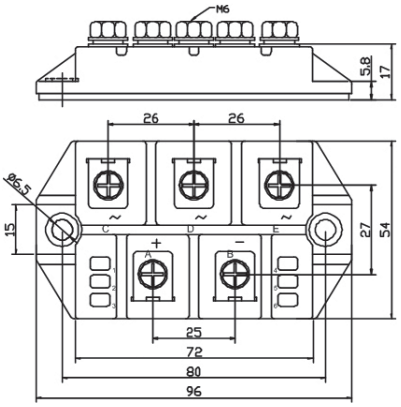
SM2-1



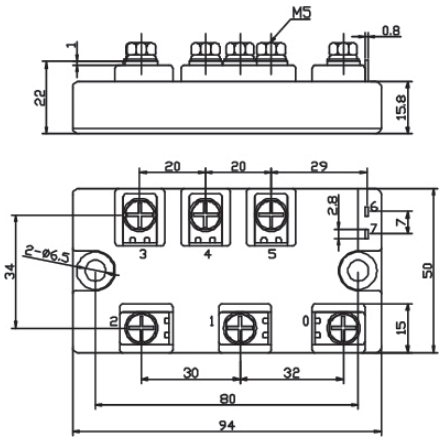
SM3



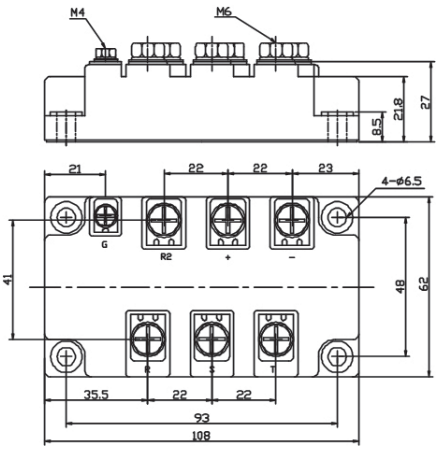
SM3-1



SM4



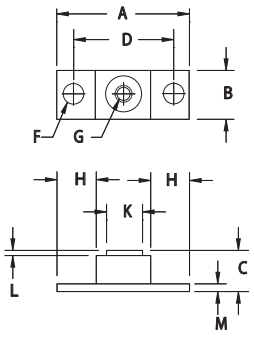
SM5



Power Module Outlines

Pin out location depends on the module configuration. Please refer to the product datasheet for pins assignment. All dimensions in millimeters.

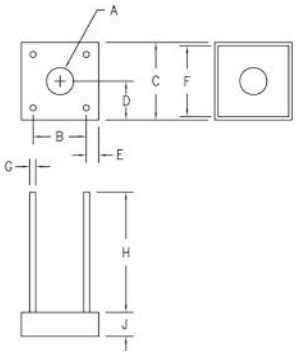
SDM



	Dim. Inches		Millimeters		
	Min.	Max.	Min.	Max.	Notes
A	---	2.650	---	67.31	
B	1.240	1.260	31.49	32.00	
C	---	.925	---	23.49	
D	2.00 BSC		50.80 BSC		
F	0.320	0.340	8.13	8.64	Dia.
G	5/16-18 UNC				
H	0.630	---	16.00	---	
K	0.610	0.640	15.49	16.26	
L	---	.100	---	2.54	
M	0.182	0.192	4.62	4.88	

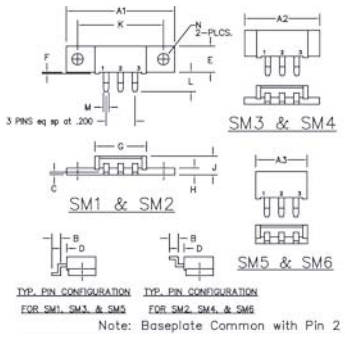
Standard Polarity: Base plate is cathode
Reverse Polarity: Base plate is anode

VJ



	Dim. Inches		Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
A	.137	.167	3.84	2.21	Dia.
B	.411	.441	10.44	11.20	
C	.600	.620	---	---	
D	.295	.310	---	---	
E	.076	.096	---	---	
F	.545	.555	13.85	14.10	
G	.076	.096	.970	1.07	
H	1.0 Min.		25.40 Min.		
J	.195	.215	4.95	5.46	

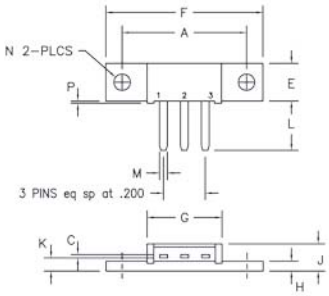
Mini-Mod Surface Mount



Note: Baseplate Common with Pin 2

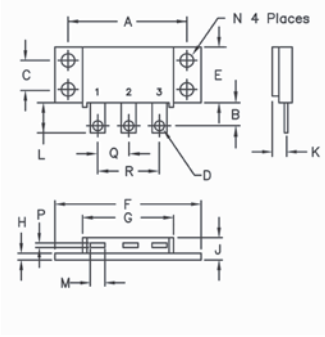
	Dim. Inches		Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
A1	1.490	1.510	37.85	38.35	
A2	1.020	1.040	26.12	26.42	
A3	.695	.715	17.65	18.16	
B	.110	.120	2.79	3.04	
C	.027	.037	0.69	0.94	
D	.100	.110	2.54	2.79	
E	.350	.370	8.89	9.40	
F	.015	.025	0.38	0.64	
G	.695	.715	17.65	18.16	
H	.088	.098	2.24	2.49	
J	.240	.260	6.10	6.60	
K	1.180	1.195	29.97	30.35	
L	.230	.250	5.84	6.35	
M	.065	.085	1.65	2.16	
N	.151	.161	3.84	4.09	Dia.

Mini-Mod



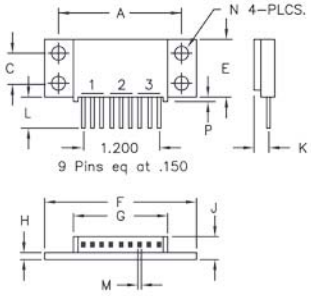
	Dim. Inches		Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
A	1.180	1.195	29.97	30.35	
C	.027	.037	0.69	0.94	
E	.350	.370	8.89	9.40	
F	1.490	1.510	37.85	38.35	
G	.695	.715	17.65	18.16	
H	.088	.098	2.24	2.49	
J	.240	.260	6.10	6.60	
K	.115	.135	2.92	3.43	
L	.460	.480	11.68	12.19	
M	.065	.085	1.65	2.16	
N	.151	.161	3.84	4.09	Dia.
P	.015	.025	0.38	0.64	

TO-249



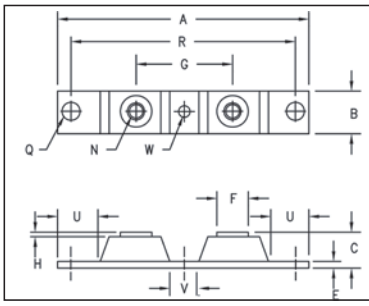
	Dim. Inches		Millimeters		
	Min.	Max.	Min.	Max.	Notes
A	1.995	2.005	50.67	50.93	
B	0.300	0.325	7.62	8.26	
C	0.495	0.505	12.57	12.83	
D	0.182	0.192	4.62	4.88	Dia.
E	0.990	1.010	25.15	25.65	
F	2.390	2.410	60.71	61.21	
G	1.500	1.525	38.10	38.70	
H	0.120	0.130	3.05	3.30	
J	---	0.400	---	10.16	
K	0.240	0.260	6.10	6.60	to Lead $\mathbb{C}_L$
L	0.490	0.510	12.45	12.95	
M	0.330	0.350	8.38	6.90	
N	0.175	0.195	4.45	4.95	Dia.
P	0.035	0.045	0.89	1.14	
Q	0.445	0.455	11.30	11.56	
R	0.890	0.910	22.61	23.11	

9 Pin TO-249



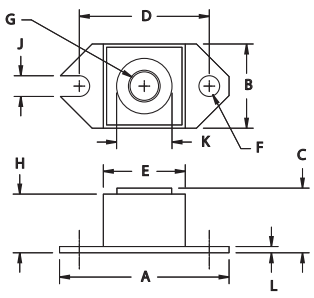
	Dim. Inches		Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
A	1.995	2.005	50.67	50.93	
C	0.495	0.506	12.57	12.83	
E	0.990	1.010	25.15	25.65	
F	2.390	2.410	60.71	61.21	
G	1.490	1.510	37.85	38.35	
H	0.120	0.130	3.05	3.30	
J	---	0.400	---	10.16	
K	0.240	0.260	6.10	6.60	to Lead $\mathbb{C}_L$
L	0.490	0.510	12.45	12.95	
M	0.040	.050	1.02	1.27	Square
N	0.175	0.195	4.45	4.95	Dia
P	0.032	0.052	0.81	1.32	

Twin Tower



	Dim. Inches		Millimeters	
	Min.	Max.	Min.	Max.
A	---	3.630	---	92.20
B	0.700	0.800	17.78	20.32
C	---	0.630	---	16.00
E	0.120	0.130	3.05	3.30
F	0.490	0.510	12.45	12.95
G	1.375 BSC		34.92 BSC	
H	0.010	---	0.25	---
N	---	---	---	---
Q	0.275	0.290	6.99	7.37
R	3.150 BSC		80.01 BSC	
U	0.600	---	15.24	---
V	0.312	0.340	7.92	8.64
W	0.180	0.195	4.57	4.95

Half Pak



	Dim. Inches		Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
A	1.52	1.56	38.61	39.62	
B	.725	.775	18.42	19.69	
C	.605	.625	15.37	15.88	
D	1.182	1.192	30.02	30.28	
E	.745	.755	18.92	19.18	Sq.
F	.152	.160	3.86	4.06	Dia.
G	1/4-20 UNC-2B				
H	.525	.580	13.34	14.73	
J	.156	.160	3.96	4.06	
K	.495	.505	12.57	12.83	Dia.
L	.120	.130	3.05	3.30	

Std. Polarity: Base is cathode
Rev. Polarity: Base is anode

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